

# TPA6211A1-Q1 3.1W、モノラル、完全差動オーディオ パワー アンプ

## 1 特長

- 車載アプリケーション認定済み
  - 温度グレード 2:  $-40^{\circ}\text{C} \sim 105^{\circ}\text{C}$   $T_A$
  - デバイス HBM ESD 分類レベル 2
  - デバイス CDM ESD 分類レベル C6
- 5V 電源から  $3\Omega$  へ 3.1W  
(THD = 10%、標準値)
- 低い消費電流: 5V で 4mA (標準値)
- シャットダウン電流:  $0.01\mu\text{A}$  (標準値)
- 最小限のポップ音で高速起動
- 3 個のみの外付け部品
  - PSRR の向上 (-80dB) と広い電源電圧範囲 (2.5V~5.5V) によりバッテリーで直接動作可能
  - 完全差動設計により RF 整流を低減
  - 63dB の CMRR により 2 つの入力カップリングコンデンサが不要

## 2 アプリケーション

- 車載用オーディオ
- 緊急通報
- ドライバーへの通知機能
- クラスA チャイム

## 3 概要

TPA6211A1-Q1 デバイスは、ほとんどの用途でプリント基板 (PCB) の占有面積がわずか  $20\text{mm}^2$  でありながら、最低  $3\Omega$  のインピーダンスのスピーカを駆動するように設計された 3.1W モノラル完全差動アンプです。本デバイスは 2.5V~5.5V で動作し、静止電流はわずか 4mA です。TPA6211A1-Q1 デバイスは省スペースの 8 ピン HVSSOP パッケージで供給されます。

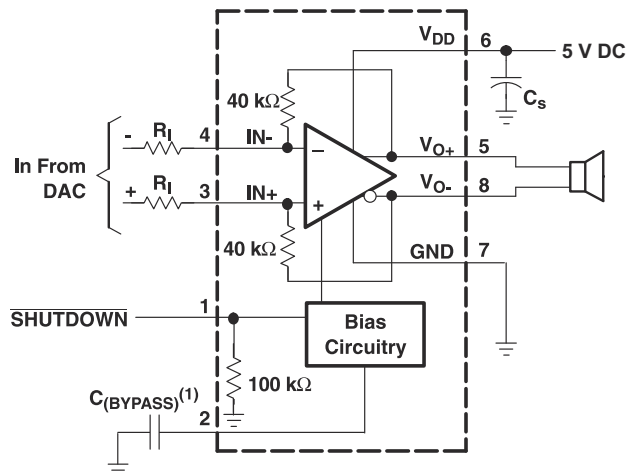
20Hz~2kHz で -80dB の電源電圧除去比、RF 整流耐性の向上、小さな PCB 占有面積、最小限のポップ音での高速起動といった特長を持つ TPA6211A1-Q1 デバイスは、緊急通報用途に優れた選択肢です。また、クラスA チャイムやドライバーへの通知機能など、インフォテインメント/クラスA用途の低消費電力ニーズにも対応します。

### 製品情報

| 部品番号         | パッケージ (1)  | パッケージ サイズ (2)   | 本体サイズ (公称)      |
|--------------|------------|-----------------|-----------------|
| TPA6211A1-Q1 | HVSSOP (8) | 3.00mm × 4.90mm | 3.00mm × 3.00mm |

(1) 詳細については、[セクション 10](#) を参照してください。

(2) パッケージ サイズ (長さ × 幅) は公称値であり、該当する場合はピンも含まれます。



A.  $C_{(BYPASS)}$  の接続は任意です

### アプリケーション回路



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## 4 Pin Configuration and Functions

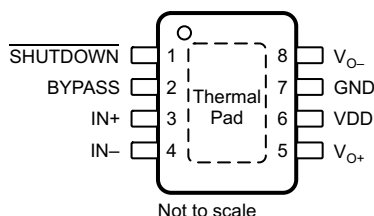


図 4-1. DGN Package 8-Pin HVSSOP Top View

### Pin Functions

| PIN             |     | I/O | DESCRIPTION                                                                                                    |
|-----------------|-----|-----|----------------------------------------------------------------------------------------------------------------|
| NAME            | NO. |     |                                                                                                                |
| BYPASS          | 2   | I   | Mid-supply voltage, adding a bypass capacitor improves PSRR                                                    |
| GND             | 7   | I   | High-current ground                                                                                            |
| IN–             | 4   | I   | Negative differential input                                                                                    |
| IN+             | 3   | I   | Positive differential input                                                                                    |
| SHUTDOWN        | 1   | I   | Shutdown pin (active low logic)                                                                                |
| Thermal Pad     | —   | —   | Connect to ground. Thermal pad must be soldered down in all applications to properly secure device on the PCB. |
| V <sub>DD</sub> | 6   | I   | Power supply                                                                                                   |
| V <sub>O+</sub> | 5   | O   | Positive BTL output                                                                                            |
| V <sub>O–</sub> | 8   | O   | Negative BTL output                                                                                            |

### 4.1 DAPPER

| NAME            | NO. | TYPE | DESCRIPTION                                                                                                    |
|-----------------|-----|------|----------------------------------------------------------------------------------------------------------------|
| BYPASS          | 2   | I    | Mid-supply voltage, adding a bypass capacitor improves PSRR                                                    |
| GND             | 7   | I    | High-current ground                                                                                            |
| IN–             | 4   | I    | Negative differential input                                                                                    |
| IN+             | 3   | I    | Positive differential input                                                                                    |
| SHUTDO<br>WN    | 1   | I    | Shutdown pin (active low logic)                                                                                |
| V <sub>DD</sub> | 6   | I    | Power supply                                                                                                   |
| V <sub>O+</sub> | 5   | O    | Positive BTL output                                                                                            |
| V <sub>O–</sub> | 8   | O    | Negative BTL output                                                                                            |
| Thermal<br>Pad  | —   | —    | Connect to ground. Thermal pad must be soldered down in all applications to properly secure device on the PCB. |

## 5 Specifications

### 5.1 Absolute Maximum Ratings

over operating free-air temperature range unless otherwise noted<sup>(1)</sup>

|                                                        | MIN                           | MAX              | UNIT |
|--------------------------------------------------------|-------------------------------|------------------|------|
| Supply voltage, $V_{DD}$                               | −0.3                          | 6                | V    |
| Input voltage, $V_I$                                   | −0.3                          | $V_{DD} + 0.3$ V | V    |
| Continuous total power dissipation                     | See <a href="#">セクション 5.7</a> |                  |      |
| Lead temperature 1.6 mm (1/16 Inch) from case for 10 s | DGN                           | 260              | °C   |
| Operating free-air temperature, $T_A$                  | −40                           | 105              | °C   |
| Junction temperature, $T_J$                            | −40                           | 150              | °C   |
| Storage temperature, $T_{stg}$                         | −65                           | 150              | °C   |

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under [セクション 5.3](#). Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### 5.2 ESD Ratings

|                                     | VALUE                                                   | UNIT  |
|-------------------------------------|---------------------------------------------------------|-------|
| $V_{(ESD)}$ Electrostatic discharge | Human-body model (HBM), per AEC Q100-002 <sup>(1)</sup> | ±2000 |
|                                     | Charged-device model (CDM), per AEC Q100-011            | ±1000 |

- (1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

### 5.3 Recommended Operating Conditions

|                                      | MIN      | MAX | UNIT |
|--------------------------------------|----------|-----|------|
| $V_{DD}$ Supply voltage              | 2.5      | 5.5 | V    |
| $V_{IH}$ High-level input voltage    | SHUTDOWN |     | V    |
| $V_{IL}$ Low-level input voltage     | SHUTDOWN | 0.5 | V    |
| $T_A$ Operating free-air temperature | −40      | 105 | °C   |

### 5.4 Thermal Information

| THERMAL METRIC <sup>(1)</sup> |                                              | TPA6211A1-Q1 | UNIT |
|-------------------------------|----------------------------------------------|--------------|------|
|                               |                                              | DGN (HVSSOP) |      |
|                               |                                              | 8 PINS       |      |
| $R_{\theta JA}$               | Junction-to-ambient thermal resistance       | 71.7         | °C/W |
| $R_{\theta JC(top)}$          | Junction-to-case (top) thermal resistance    | 55.9         | °C/W |
| $R_{\theta JB}$               | Junction-to-board thermal resistance         | 44.9         | °C/W |
| $\psi_{JT}$                   | Junction-to-top characterization parameter   | 3.7          | °C/W |
| $\psi_{JB}$                   | Junction-to-board characterization parameter | 44.7         | °C/W |
| $R_{\theta JC(bot)}$          | Junction-to-case (bottom) thermal resistance | 19.6         | °C/W |

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

### 5.5 Electrical Characteristics

$T_A = 25^\circ\text{C}$

| PARAMETER                                                | TEST CONDITIONS                                           | MIN | TYP | MAX | UNIT |
|----------------------------------------------------------|-----------------------------------------------------------|-----|-----|-----|------|
| $V_{OS}$ Output offset voltage (measured differentially) | $V_I = 0$ -V differential, Gain = 1 V/V, $V_{DD} = 5.5$ V | −9  | 0.3 | 9   | mV   |
| PSRR Power supply rejection ratio                        | $V_{DD} = 2.5$ V to 5.5 V                                 |     | −85 | −60 | dB   |

$T_A = 25^\circ\text{C}$ 

| PARAMETER                                     | TEST CONDITIONS                                                                                                                 | MIN                             | TYP                             | MAX                             | UNIT          |
|-----------------------------------------------|---------------------------------------------------------------------------------------------------------------------------------|---------------------------------|---------------------------------|---------------------------------|---------------|
| $V_{IC}$ Common mode input range              | $V_{DD} = 2.5\text{ V to }5.5\text{ V}$                                                                                         | 0.5                             |                                 | $V_{DD} - 0.8$                  | V             |
| $CMRR$ Common mode rejection ratio            | $V_{DD} = 5.5\text{ V}, V_{IC} = 0.5\text{ V to }4.7\text{ V}$                                                                  |                                 | –63                             | –40                             | dB            |
|                                               | $V_{DD} = 2.5\text{ V}, V_{IC} = 0.5\text{ V to }1.7\text{ V}$                                                                  |                                 | –63                             | –40                             |               |
| Low-output swing                              | $R_L = 4\ \Omega, V_{IN+} = V_{DD}, V_{IN-} = 0\text{ V},$<br>Gain = $1\text{ V/V}, V_{IN-} = 0\text{ V}$ or $V_{IN+} = V_{DD}$ | $V_{DD} = 5.5\text{ V}$         | 0.45                            |                                 | V             |
|                                               |                                                                                                                                 | $V_{DD} = 3.6\text{ V}$         | 0.37                            |                                 |               |
|                                               |                                                                                                                                 | $V_{DD} = 2.5\text{ V}$         | 0.26                            | 0.4                             |               |
| High-output swing                             | $R_L = 4\ \Omega, V_{IN+} = V_{DD}, V_{IN-} = V_{DD},$<br>Gain = $1\text{ V/V}, V_{IN-} = 0\text{ V}$ or $V_{IN+} = 0\text{ V}$ | $V_{DD} = 5.5\text{ V}$         | 4.95                            |                                 | V             |
|                                               |                                                                                                                                 | $V_{DD} = 3.6\text{ V}$         | 3.18                            |                                 |               |
|                                               |                                                                                                                                 | $V_{DD} = 2.5\text{ V}$         | 2                               | 2.13                            |               |
| $ I_{IH} $ High-level input current, shutdown | $V_{DD} = 5.5\text{ V}, V_I = 5.8\text{ V}$                                                                                     |                                 | 58                              | 100                             | $\mu\text{A}$ |
| $ I_{IL} $ Low-level input current, shutdown  | $V_{DD} = 5.5\text{ V}, V_I = -0.3\text{ V}$                                                                                    |                                 | 3                               | 100                             | $\mu\text{A}$ |
| $I_Q$ Quiescent current                       | $V_{DD} = 2.5\text{ V to }5.5\text{ V},$ no load                                                                                |                                 | 4                               | 5                               | mA            |
| $I_{(SD)}$ Supply current                     | $V_{SHUTDOWN} \leq 0.5\text{ V}, V_{DD} = 2.5\text{ V to }5.5\text{ V}, R_L = 4\ \Omega$                                        |                                 | 0.01                            | 1                               | $\mu\text{A}$ |
| Gain                                          | $R_L = 4\ \Omega$                                                                                                               | $\frac{38\text{ k}\Omega}{R_I}$ | $\frac{40\text{ k}\Omega}{R_I}$ | $\frac{42\text{ k}\Omega}{R_I}$ | V/V           |
| Resistance from shutdown to GND               |                                                                                                                                 |                                 | 100                             |                                 | k $\Omega$    |

## 5.6 Operating Characteristics

$T_A = 25^\circ\text{C}$ , Gain = 1 V/V

| PARAMETER                                  | TEST CONDITIONS                                                                                                 |                                                 | MIN | TYP    | MAX | UNIT                |
|--------------------------------------------|-----------------------------------------------------------------------------------------------------------------|-------------------------------------------------|-----|--------|-----|---------------------|
| $P_O$ Output power                         | THD + N = 1%, $f = 1\text{ kHz}$ , $R_L = 3\ \Omega$                                                            | $V_{DD} = 5\text{ V}$                           |     | 2.45   |     | W                   |
|                                            |                                                                                                                 | $V_{DD} = 3.6\text{ V}$                         |     | 1.22   |     |                     |
|                                            |                                                                                                                 | $V_{DD} = 2.5\text{ V}$                         |     | 0.49   |     |                     |
|                                            | THD + N = 1%, $f = 1\text{ kHz}$ , $R_L = 4\ \Omega$                                                            | $V_{DD} = 5\text{ V}$                           |     | 2.22   |     |                     |
|                                            |                                                                                                                 | $V_{DD} = 3.6\text{ V}$                         |     | 1.1    |     |                     |
|                                            |                                                                                                                 | $V_{DD} = 2.5\text{ V}$                         |     | 0.47   |     |                     |
|                                            | THD + N = 1%, $f = 1\text{ kHz}$ , $R_L = 8\ \Omega$                                                            | $V_{DD} = 5\text{ V}$                           |     | 1.36   |     |                     |
|                                            |                                                                                                                 | $V_{DD} = 3.6\text{ V}$                         |     | 0.72   |     |                     |
|                                            |                                                                                                                 | $V_{DD} = 2.5\text{ V}$                         |     | 0.33   |     |                     |
| THD+N Total harmonic distortion plus noise | $f = 1\text{ kHz}$ , $R_L = 3\ \Omega$                                                                          | $P_O = 2\text{ W}$ , $V_{DD} = 5\text{ V}$      |     | 0.045% |     |                     |
|                                            |                                                                                                                 | $P_O = 1\text{ W}$ , $V_{DD} = 3.6\text{ V}$    |     | 0.05%  |     |                     |
|                                            |                                                                                                                 | $P_O = 300\text{ mW}$ , $V_{DD} = 2.5\text{ V}$ |     | 0.06%  |     |                     |
|                                            | $f = 1\text{ kHz}$ , $R_L = 4\ \Omega$                                                                          | $P_O = 1.8\text{ W}$ , $V_{DD} = 5\text{ V}$    |     | 0.03%  |     |                     |
|                                            |                                                                                                                 | $P_O = 0.7\text{ W}$ , $V_{DD} = 3.6\text{ V}$  |     | 0.03%  |     |                     |
|                                            |                                                                                                                 | $P_O = 300\text{ mW}$ , $V_{DD} = 2.5\text{ V}$ |     | 0.04%  |     |                     |
|                                            | $f = 1\text{ kHz}$ , $R_L = 8\ \Omega$                                                                          | $P_O = 1\text{ W}$ , $V_{DD} = 5\text{ V}$      |     | 0.02%  |     |                     |
|                                            |                                                                                                                 | $P_O = 0.5\text{ W}$ , $V_{DD} = 3.6\text{ V}$  |     | 0.02%  |     |                     |
|                                            |                                                                                                                 | $P_O = 200\text{ mW}$ , $V_{DD} = 2.5\text{ V}$ |     | 0.03%  |     |                     |
| $k_{SVR}$ Supply ripple rejection ratio    | $V_{DD} = 3.6\text{ V}$ , Inputs AC-grounded with $C_I = 2\ \mu\text{F}$ , $V_{RIPPLE} = 200\text{ mV}_{pp}$    | $f = 217\text{ Hz}$                             |     | –80    |     | dB                  |
|                                            |                                                                                                                 | $f = 20\text{ Hz to } 20\text{ kHz}$            |     | –70    |     |                     |
| SNR Signal-to-noise ratio                  | $V_{DD} = 5\text{ V}$ , $P_O = 2\text{ W}$ , $R_L = 4\ \Omega$                                                  |                                                 |     | 105    |     | dB                  |
| $V_n$ Output voltage noise                 | $V_{DD} = 3.6\text{ V}$ , $f = 20\text{ Hz to } 20\text{ kHz}$ , Inputs AC-grounded with $C_I = 2\ \mu\text{F}$ | No weighting                                    |     | 15     |     | $\mu\text{V}_{RMS}$ |
|                                            |                                                                                                                 | A weighting                                     |     | 12     |     |                     |
| CMRR Common mode rejection ratio           | $V_{DD} = 3.6\text{ V}$ , $V_{IC} = 1\text{ V}_{pp}$                                                            |                                                 |     | –65    |     | dB                  |
| $Z_I$ Input impedance                      |                                                                                                                 |                                                 | 38  | 40     | 44  | k $\Omega$          |
| Start-up time from shutdown                | $V_{DD} = 3.6\text{ V}$ , No $C_{BYPASS}$                                                                       |                                                 |     | 4      |     | $\mu\text{s}$       |
|                                            | $V_{DD} = 3.6\text{ V}$ , $C_{BYPASS} = 0.1\ \mu\text{F}$                                                       |                                                 |     | 27     |     | ms                  |

## 5.7 Dissipation Ratings

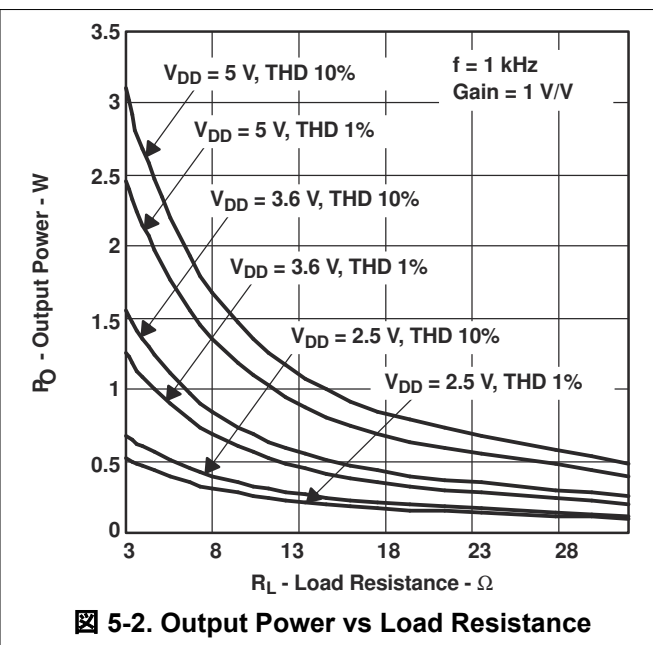
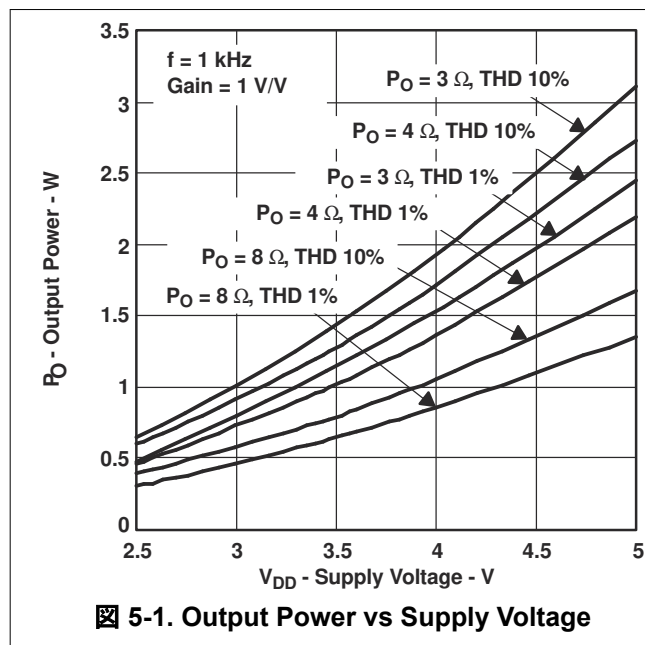
| PACKAGE | $T_A \leq 25^\circ\text{C}$<br>POWER RATING | DERATING<br>FACTOR <sup>(1)</sup> | $T_A = 70^\circ\text{C}$<br>POWER RATING | $T_A = 85^\circ\text{C}$<br>POWER RATING |
|---------|---------------------------------------------|-----------------------------------|------------------------------------------|------------------------------------------|
| DGN     | 2.13 W                                      | 17.1 mW/ $^\circ\text{C}$         | 1.36 W                                   | 1.11 W                                   |

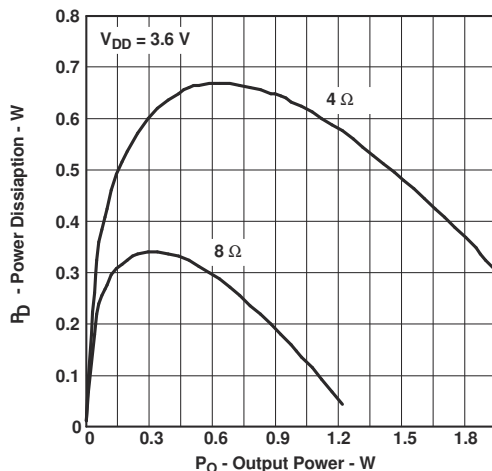
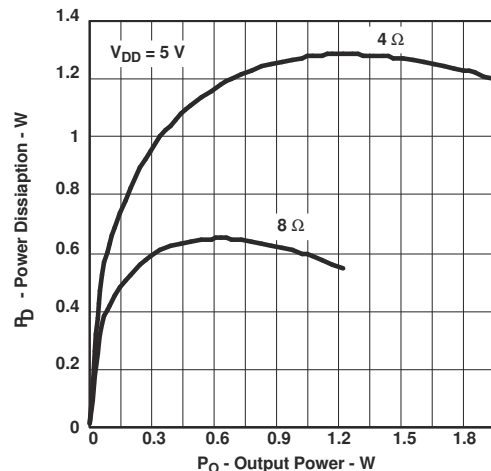
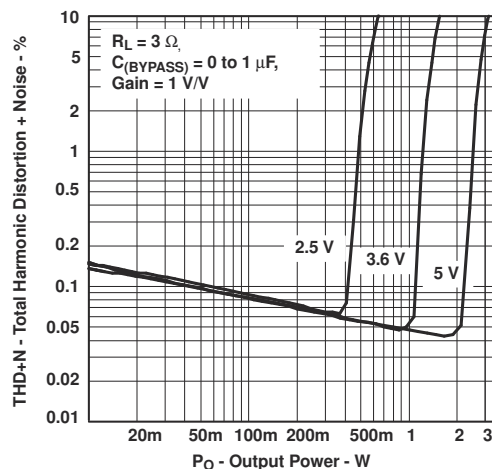
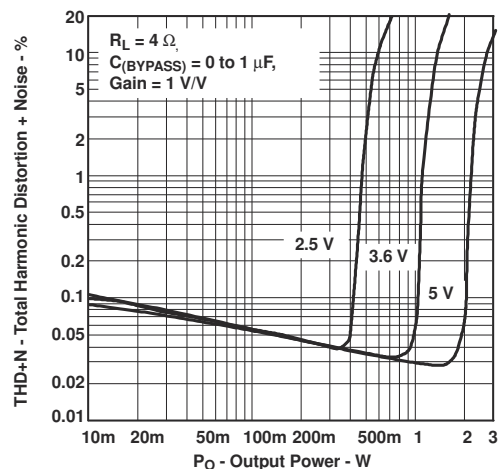
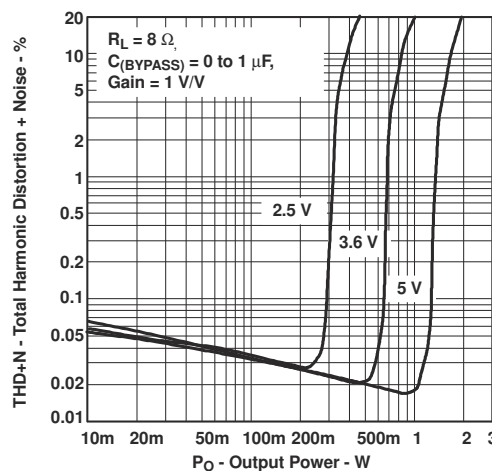
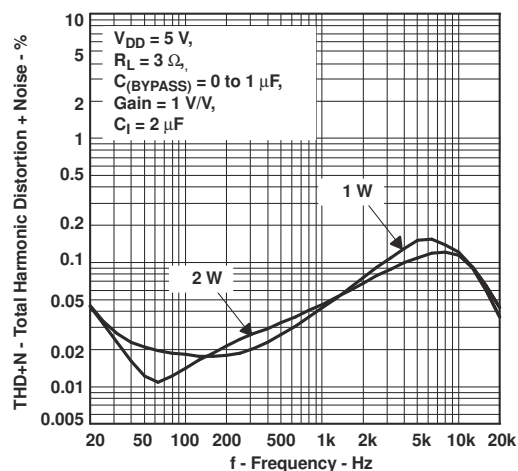
(1) Derating factor based on High-k board layout.

## Typical Characteristics

表 5-1. Table of Graphs

|                                   |                              | FIGURE                               |
|-----------------------------------|------------------------------|--------------------------------------|
| Output power                      | vs Supply voltage            | 図 5-1                                |
|                                   | vs Load resistance           | 図 5-2                                |
| Power dissipation                 | vs Output power              | 図 5-3, 図 5-4                         |
| Total harmonic distortion + noise | vs Output power              | 図 5-5, 図 5-6, 図 5-7                  |
|                                   | vs Frequency                 | 図 5-8, 図 5-9, 図 5-10, 図 5-11, 図 5-12 |
|                                   | vs Common-mode input voltage | 図 5-13                               |
| Supply voltage rejection ratio    | vs Frequency                 | 図 5-14, 図 5-15, 図 5-16, 図 5-17       |
| Supply voltage rejection ratio    | vs Common-mode input voltage | 図 5-18                               |
| GSM Power supply rejection        | vs Time                      | 図 5-19                               |
| GSM Power supply rejection        | vs Frequency                 | 図 5-20                               |
| Common-mode rejection ratio       | vs Frequency                 | 図 5-21                               |
|                                   | vs Common-mode input voltage | 図 5-22                               |
| Closed loop gain/phase            | vs Frequency                 | 図 5-23                               |
| Open loop gain/phase              | vs Frequency                 | 図 5-24                               |
| Supply current                    | vs Supply voltage            | 図 5-25                               |
|                                   | vs Shutdown voltage          | 図 5-26                               |
| Start-up time                     | vs Bypass capacitor          | 図 5-27                               |




 5-3. Power Dissipation vs Output Power

 5-4. Power Dissipation vs Output Power

 5-5. Total Harmonic Distortion + Noise vs Output Power

 5-6. Total Harmonic Distortion + Noise vs Output Power

 5-7. Total Harmonic Distortion + Noise vs Output Power

 5-8. Total Harmonic Distortion + Noise vs Frequency

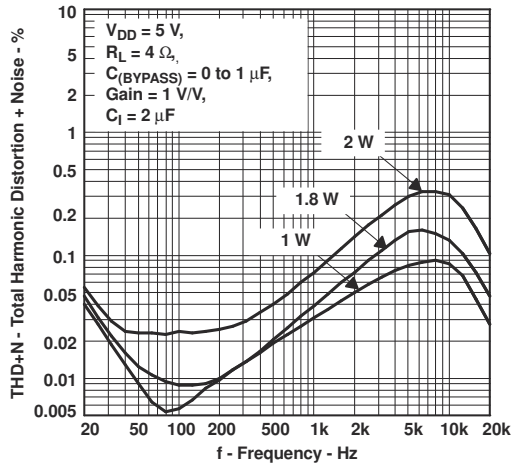


Figure 5-9. Total Harmonic Distortion + Noise vs Frequency

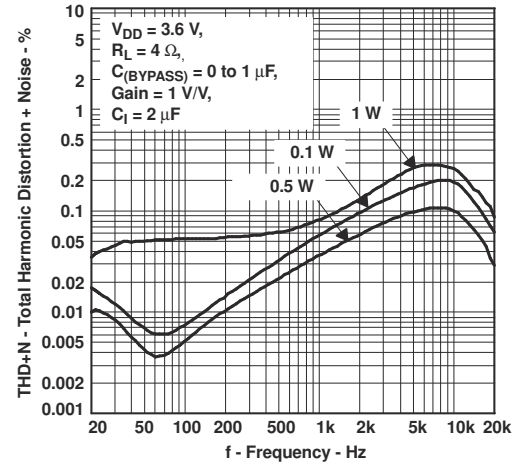


Figure 5-10. Total Harmonic Distortion + Noise vs Frequency

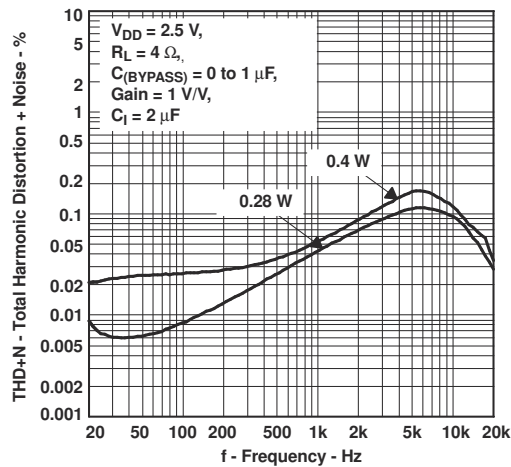


Figure 5-11. Total Harmonic Distortion + Noise vs Frequency

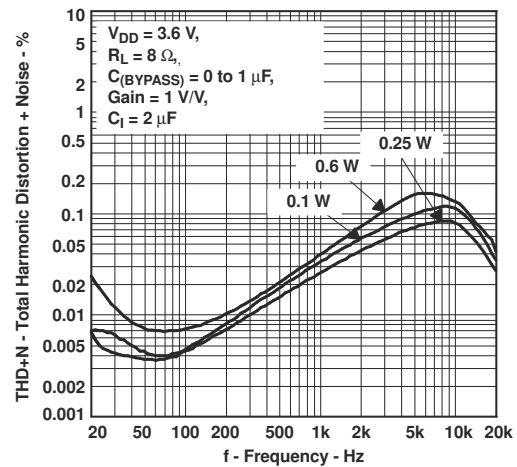


Figure 5-12. Total Harmonic Distortion + Noise vs Frequency

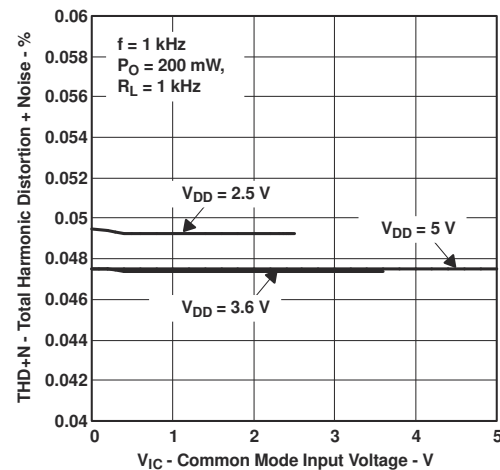


Figure 5-13. Total Harmonic Distortion + Noise vs Common-Mode Input Voltage

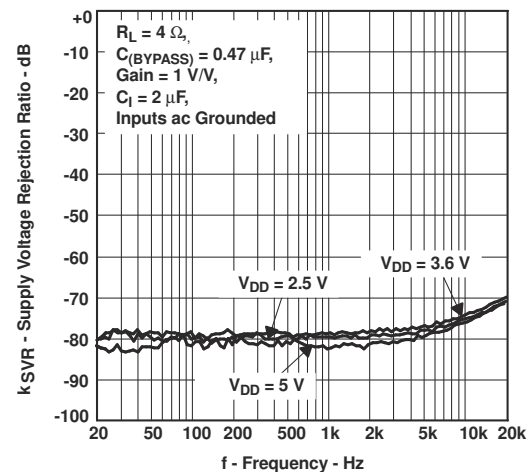
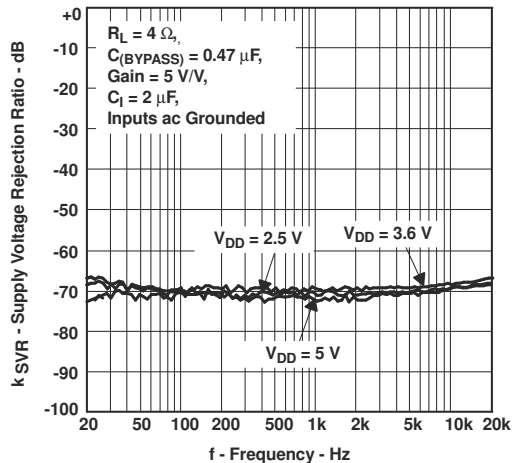
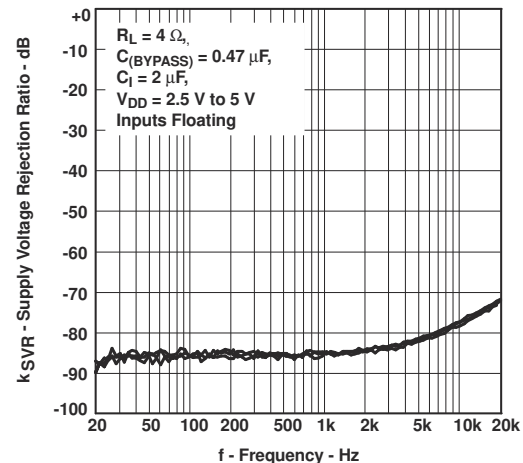


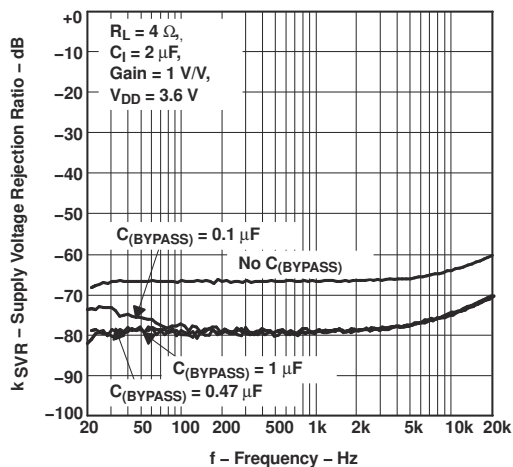
Figure 5-14. Supply Voltage Rejection Ratio vs Frequency



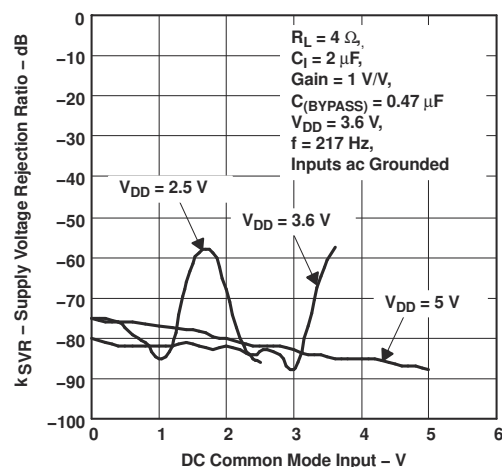
5-15. Supply Voltage Rejection Ratio vs Frequency



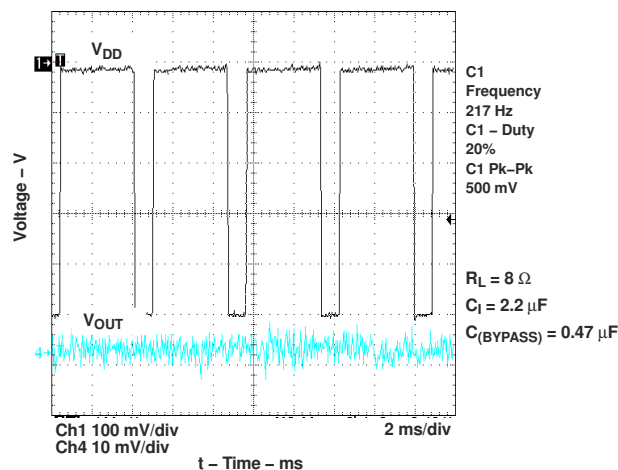
5-16. Supply Ripple Rejection Ratio vs Frequency



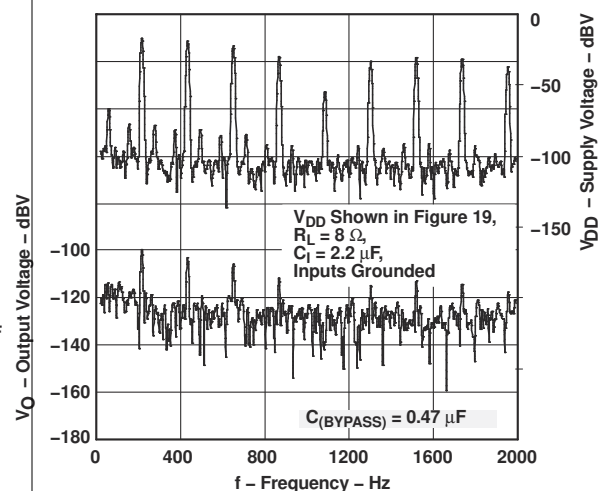
5-17. Supply Voltage Rejection Ratio vs Frequency



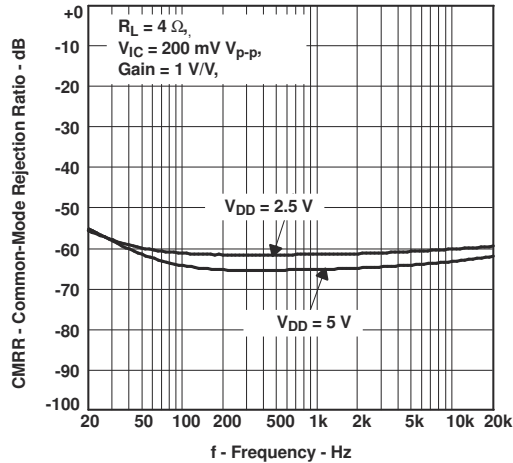
5-18. Supply Voltage Rejection Ratio vs DC Common-Mode Input



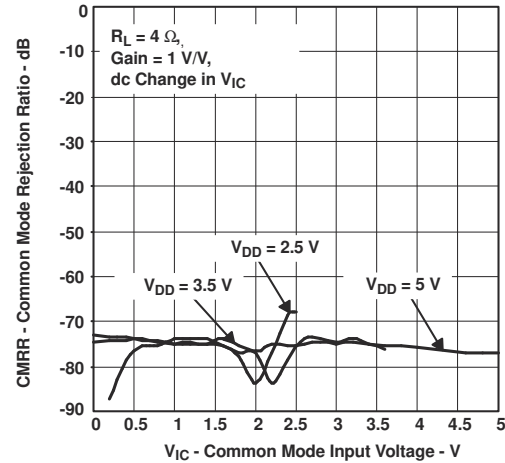
5-19. GSM Power Supply Rejection vs Time



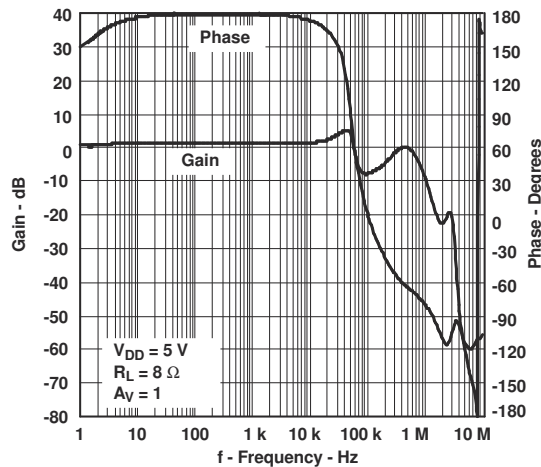
5-20. GSM Power Supply Rejection vs Frequency



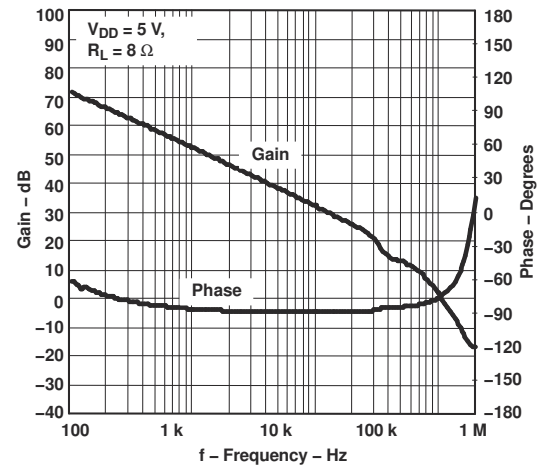
5-21. Common-Mode Rejection Ratio vs Frequency



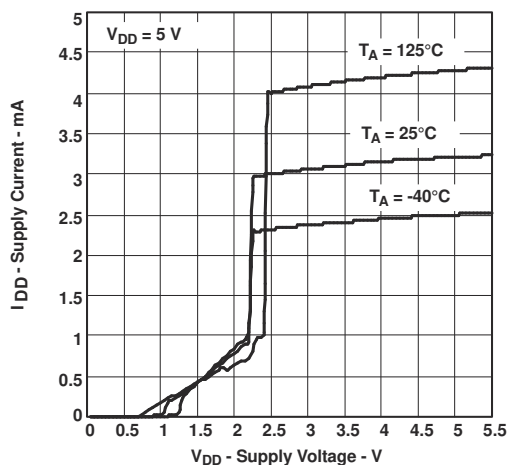
5-22. Common-Mode Rejection Ratio vs Common-Mode Input Voltage



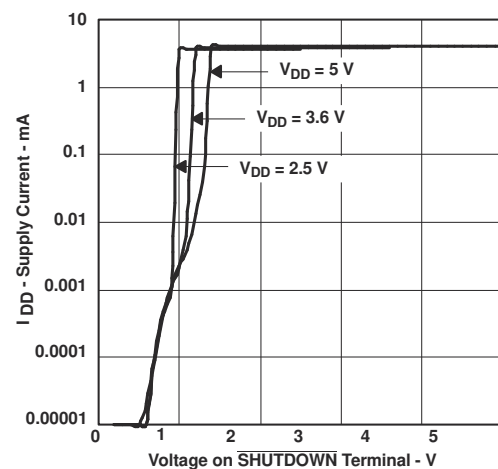
5-23. Closed Loop Gain/Phase vs Frequency



5-24. Open Loop Gain/Phase vs Frequency



5-25. Supply Current vs Supply Voltage



5-26. Supply Current vs Shutdown Voltage

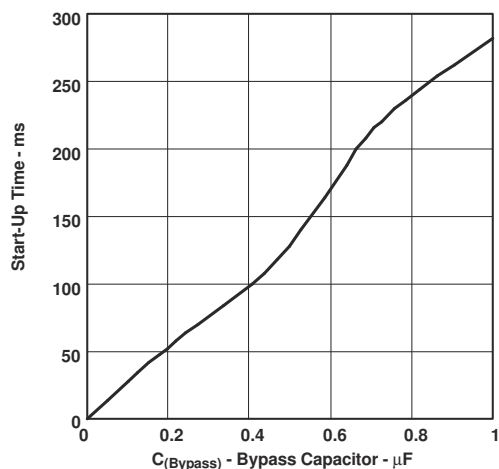


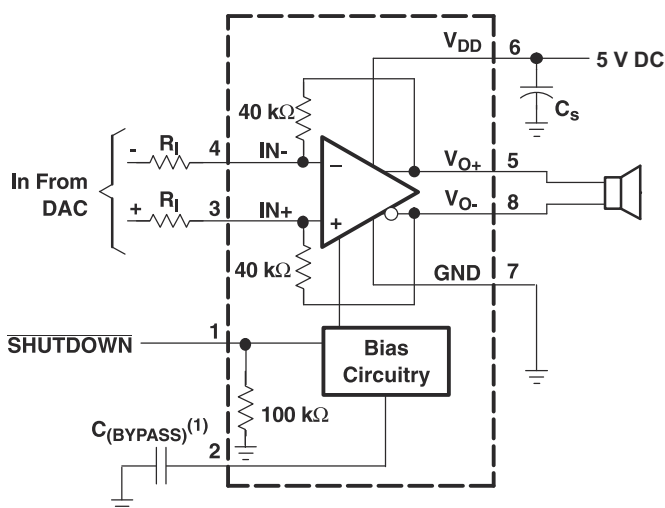
図 5-27. Start-up Time vs Bypass Capacitor

## 6 Detailed Description

### 6.1 Overview

The TPA6211A1-Q1 device is a fully differential amplifier with differential inputs and outputs. The fully differential amplifier consists of a differential amplifier and a common-mode amplifier. The differential amplifier ensures that the amplifier outputs a differential voltage that is equal to the differential input times the gain. The common-mode feedback ensures that the common-mode voltage at the output is biased around  $V_{DD} / 2$  regardless of the common-mode voltage at the input.

### 6.2 Functional Block Diagram



A.  $C_{(BYPASS)}$  is optional

### 6.3 Feature Description

#### 6.3.1 Advantages of Fully Differential Amplifiers

Input coupling capacitors are not required. A fully differential amplifier with good CMRR, such as the TPA6211A1-Q1 device, allows the inputs to be biased at voltage other than mid-supply. For example, if a DAC has a lower mid-supply voltage than that of the TPA6211A1-Q1 device, the common-mode feedback circuit compensates, and the outputs are still biased at the mid-supply point of the TPA6211A1-Q1 device. The inputs of the TPA6211A1-Q1 device can be biased from 0.5 V to  $V_{DD} - 0.8$  V. If the inputs are biased outside of that range, input coupling capacitors are required.

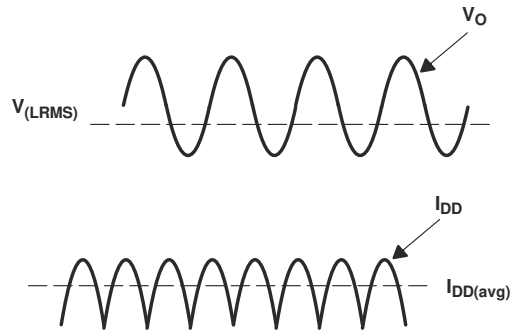
A Mid-supply bypass capacitor,  $C_{BYPASS}$ , is not required. The fully differential amplifier does not require a bypass capacitor. Any shift in the mid-supply voltage affects both positive and negative channels equally, thus canceling at the differential output. Removing the bypass capacitor slightly worsens power supply rejection ratio ( $k_{SVR}$ ), but a slight decrease of  $k_{SVR}$  can be acceptable when an additional component can be eliminated (see [Figure 5-17](#)).

The RF-immunity is improved. A fully differential amplifier cancels the noise from RF disturbances much better than the typical audio amplifier.

#### 6.3.2 Fully Differential Amplifier Efficiency and Thermal Information

Class-AB amplifiers are inefficient, primarily because of voltage drop across the output-stage transistors. The two components of this internal voltage drop are the headroom or DC voltage drop that varies inversely to output power, and the sinewave nature of the output. The total voltage drop can be calculated by subtracting the RMS value of the output voltage from  $V_{DD}$ . The internal voltage drop multiplied by the average value of the supply current,  $I_{DD}(avg)$ , determines the internal power dissipation of the amplifier.

An easy-to-use equation to calculate efficiency starts out as being equal to the ratio of power from the power supply to the power delivered to the load. To accurately calculate the RMS and average values of power in the load and in the amplifier, the current and voltage waveform shapes must first be understood (see [Figure 6-1](#)).



**Figure 6-1. Voltage and Current Waveforms for BTL Amplifiers**

Although the voltages and currents for SE and BTL are sinusoidal in the load, currents from the supply are different between SE and BTL configurations. In an SE application the current waveform is a half-wave rectified shape, whereas in BTL the current waveform is a full-wave rectified waveform. This means RMS conversion factors are different. Keep in mind that for most of the waveform both the push and pull transistors are not on at the same time, which supports the fact that each amplifier in the BTL device only draws current from the supply for half the waveform. [Equation 2](#) to [Equation 11](#) are the basis for calculating amplifier efficiency.

$$\text{Efficiency of a BTL amplifier} = \frac{P_L}{P_{SUP}}$$

Where:

$$P_L = \frac{V_{L\text{rms}}^2}{R_L}, \text{ and } V_{LRMS} = \frac{V_P}{\sqrt{2}}, \text{ therefore, } P_L = \frac{V_P^2}{2R_L}$$

$$\text{and } P_{SUP} = V_{DD} I_{DD\text{avg}} \text{ and } I_{DD\text{avg}} = \frac{1}{\pi} \int_0^\pi \frac{V_P}{R_L} \sin(t) dt = -\frac{1}{\pi} \times \frac{V_P}{R_L} [\cos(t)]_0^\pi = \frac{2V_P}{\pi R_L}$$

Therefore,

$$P_{SUP} = \frac{2 V_{DD} V_P}{\pi R_L}$$

substituting  $P_L$  and  $P_{SUP}$  into equation 6,

$$\text{Efficiency of a BTL amplifier} = \frac{\frac{V_P^2}{2R_L}}{\frac{2 V_{DD} V_P}{\pi R_L}} = \frac{\pi V_P}{4 V_{DD}}$$

Where:

$$V_P = \sqrt{2 P_L R_L}$$

$$\eta_{BTL} = \frac{P_L}{P_{SUP}}$$

$P_L$  = Power delivered to load  
 $P_{SUP}$  = Power drawn from power supply  
 $V_{LRMS}$  = RMS voltage on BTL load  
 $R_L$  = Load resistance  
 $V_P$  = Peak voltage on BTL load  
 $I_{DD\text{avg}}$  = Average current drawn from the power supply  
 $V_{DD}$  = Power supply voltage  
 $\eta_{BTL}$  = Efficiency of a BTL amplifier

(1)

(2)

where

- $\eta_{BTL}$  is the efficiency of a BTL amplifier
- $P_L$  is the power delivered to load

- $P_{SUP}$  is the power drawn from power supply

$P_L$  is calculated with 式 3, and  $V_{LRMS}$  is calculated with 式 4.

$$P_L = \frac{V_{LRMS}^2}{R_L} \quad (3)$$

where

- $V_{LRMS}$  = RMS voltage on BTL load
- $R_L$  is load resistance

$$V_{LRMS} = \frac{V_P}{\sqrt{2}} \quad (4)$$

where

- $V_P$  is peak voltage on BTL load

Therefore,  $P_L$  can be given as 式 5.

$$P_L = \frac{V_P^2}{2 \times R_L} \quad (5)$$

$P_{SUP}$  is calculated with 式 6.

$$P_{SUP} = V_{DD} \times I_{DDavg} \quad (6)$$

where

- $V_{DD}$  is power supply voltage
- $I_{DDavg}$  is average current drawn from the power supply

$I_{DDavg}$  is calculated with 式 7.

$$I_{DDavg} = \frac{1}{\pi} \int_0^\pi \frac{V_P}{R_L} \times \sin(t) \times dt = -\frac{1}{\pi} \times \frac{V_P}{R_L} \times \cos(t) \Big|_0^\pi = \frac{2 \times V_P}{\pi \times R_L} \quad (7)$$

Therefore,  $P_{SUP}$  can be given as 式 8.

$$P_{SUP} = \frac{2 \times V_{DD} \times V_P}{\pi \times R_L} \quad (8)$$

Substituting for  $P_L$  and  $P_{SUP}$ , 式 2 becomes 式 9

$$\eta_{BTL} = \frac{\frac{V_P^2}{2 \times R_L}}{\frac{2 \times V_{DD} \times V_P}{\pi \times R_L}} = \frac{\pi \times V_P}{4 \times V_{DD}} \quad (9)$$

$V_P$  is calculated with 式 10.

$$V_P = \sqrt{2 \times P_L \times R_L} \quad (10)$$

And substituting for  $V_P$ ,  $\eta_{BTL}$  can be calculated with 式 11

$$\eta_{\text{BTL}} = \frac{\pi \sqrt{2 \times P_L \times R_L}}{4 \times V_{\text{DD}}} \quad (11)$$

A simple formula for calculating the maximum power dissipated ( $P_{\text{Dmax}}$ ) can be used for a differential output application:

$$P_{\text{Dmax}} = \frac{2V_{\text{DD}}^2}{\pi^2 R_L} \quad (12)$$

**表 6-1. Efficiency and Maximum Ambient Temperature vs Output Power**

| OUTPUT POWER                | EFFICIENCY | INTERNAL DISSIPATION | POWER FROM SUPPLY | MAX AMBIENT TEMPERATURE                                      |
|-----------------------------|------------|----------------------|-------------------|--------------------------------------------------------------|
| <b>5-V, 3-Ω SYSTEMS</b>     |            |                      |                   |                                                              |
| 0.5 W                       | 27.2%      | 1.34 W               | 1.84 W            | 54°C                                                         |
| 1 W                         | 38.4%      | 1.6 W                | 2.6 W             | 35°C                                                         |
| 2.45 W                      | 60.2%      | 1.62 W               | 4.07 W            | 34°C                                                         |
| 3.1 W                       | 67.7%      | 1.48 W               | 4.58 W            | 44°C                                                         |
| <b>5-V, 4-Ω BTL SYSTEMS</b> |            |                      |                   |                                                              |
| 0.5 W                       | 31.4%      | 1.09 W               | 1.59 W            | 72°C                                                         |
| 1 W                         | 44.4%      | 1.25 W               | 2.25 W            | 60°C                                                         |
| 2 W                         | 62.8%      | 1.18 W               | 3.18 W            | 65°C                                                         |
| 2.8 W                       | 74.3%      | 0.97 W               | 3.77 W            | 80°C                                                         |
| <b>5-V, 8-Ω SYSTEMS</b>     |            |                      |                   |                                                              |
| 0.5 W                       | 44.4%      | 0.625 W              | 1.13 W            | 105°C (limited by maximum ambient temperature specification) |
| 1 W                         | 62.8%      | 0.592 W              | 1.6 W             | 105°C (limited by maximum ambient temperature specification) |
| 1.36 W                      | 73.3%      | 0.496 W              | 1.86 W            | 105°C (limited by maximum ambient temperature specification) |
| 1.7 W                       | 81.9%      | 0.375 W              | 2.08 W            | 105°C (limited by maximum ambient temperature specification) |

式 11 is used to calculate efficiencies for four different output power levels, see 表 6-1. The efficiency of the amplifier is quite low for lower power levels and rises sharply as power to the load is increased resulting in a nearly flat internal power dissipation over the normal operating range. The internal dissipation at full output power is less than in the half power range. Calculating the efficiency for a specific system is the key to proper power supply design. For a 2.8-W audio system with 4-Ω loads and a 5-V supply, the maximum draw on the power supply is almost 3.8 W.

A final point to remember about Class-AB amplifiers is how to manipulate the terms in the efficiency equation to the utmost advantage when possible. In 式 11,  $V_{\text{DD}}$  is in the denominator. This indicates that as  $V_{\text{DD}}$  goes down, efficiency goes up.

The maximum ambient temperature depends on the heat sinking ability of the PCB system. Given  $R_{\theta \text{ JA}}$  (junction-to-ambient thermal resistance), the maximum allowable junction temperature, and the internal dissipation at 1-W output power with a 4-Ohm load, the maximum ambient temperature can be calculated with 式 13. The maximum recommended junction temperature for the TPA6211A1-Q1 device is 150°C.

$$T_A(\text{Max}) = T_J(\text{Max}) - R_{\theta \text{ JA}} \times P_D = 150 - 71.7 \times 1.25 = 60^\circ\text{C} \quad (13)$$

式 13 shows that the maximum ambient temperature is 60°C at 1-W output power and 4-Ohm load with a 5-V supply.

表 6-1 shows that the thermal performance must be considered when using a Class-AB amplifier to keep junction temperatures in the specified range. The TPA6211A1-Q1 device is designed with thermal protection that turns the device off when the junction temperature surpasses 150°C to prevent damage to the IC. In addition, using speakers with an impedance higher than 4 Ω dramatically increases the thermal performance by reducing the output current.

### 6.3.3 Differential Output Versus Single-Ended Output

図 6-2 shows a Class-AB audio power amplifier (APA) in a fully differential configuration. The TPA6211A1-Q1 amplifier has differential outputs driving both ends of the load. One of several potential benefits to this configuration is power to the load. The differential drive to the speaker means that as one side is slewing up, the other side is slewing down, and vice versa. This in effect doubles the voltage swing on the load as compared to a ground-referenced load. Plugging  $2 \times V_{O(PP)}$  into the power equation (式 14) yields four-times the output power (as the voltage is squared) from the same supply rail and load impedance (see 式 16 and 式 17).

$$V_{(rms)} = \frac{V_{O(PP)}}{2\sqrt{2}}$$

$$Power = \frac{V_{(rms)}^2}{R_L} \quad (14)$$

$$Power_{(S-E)} = \frac{V_{(rms)}^2}{R_L} = \frac{\left(\frac{V_{O(PP)}}{2\sqrt{2}}\right)^2}{R_L} = \frac{V_{O(PP)}^2}{8R_L} \quad (15)$$

$$Power_{(Diff)} = \frac{V_{(rms)}^2}{R_L} = \frac{\left(\frac{2 \times V_{O(PP)}}{2\sqrt{2}}\right)^2}{R_L} = \frac{V_{O(PP)}^2}{2R_L} \quad (16)$$

$$Power_{(Diff)} = 4 \times Power_{(S-E)} \quad (17)$$

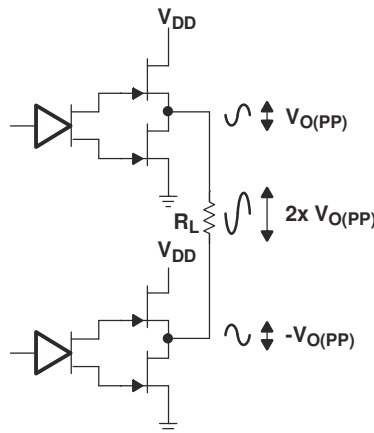


図 6-2. Differential Output Configuration

In a typical automotive application operating at 5 V, bridging raises the power into an 8-Ω speaker from a singled-ended (SE, ground reference) limit of 390 mW to 1.56 W. This is a 6-dB improvement in sound power, or loudness of the sound. In addition to increased power, there are frequency-response concerns. Consider the single-supply SE configuration shown in 図 6-3. A coupling capacitor ( $C_C$ ) is required to block the DC-offset voltage from the load. This capacitor can be quite large (approximately 33 μF to 1000 μF) so it tends to be

expensive, heavy, occupy valuable PCB area, and have the additional drawback of limiting low-frequency performance. This frequency-limiting effect is due to the high-pass filter network created with the speaker impedance and the coupling capacitance. This is calculated with 式 18.

$$f_c = \frac{1}{2\pi R_L C_C} \quad (18)$$

For example, a 68-μF capacitor with an 8-Ω speaker would attenuate low frequencies below 293 Hz. The BTL configuration cancels the DC offsets, which eliminates the need for the blocking capacitors. Low-frequency performance is then limited only by the input network and speaker response. Cost and PCB space are also minimized by eliminating the bulky coupling capacitor.

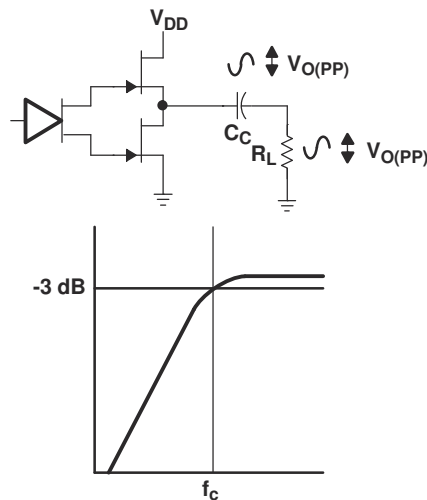


図 6-3. Single-Ended Output and Frequency Response

Increasing power to the load does carry a penalty of increased internal power dissipation. The increased dissipation is understandable considering that the BTL configuration produces four-times the output power of the SE configuration.

## 6.4 Device Functional Modes

The TPA6211A1-Q1 device can be put in shutdown mode when asserting **SHUTDOWN** pin to a logic LOW. While in shutdown mode, the device output stage is turned off and set into high impedance, making the current consumption very low. The device exits shutdown mode when a HIGH logic level is applied to **SHUTDOWN** pin.

## 7 Application and Implementation

### 注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

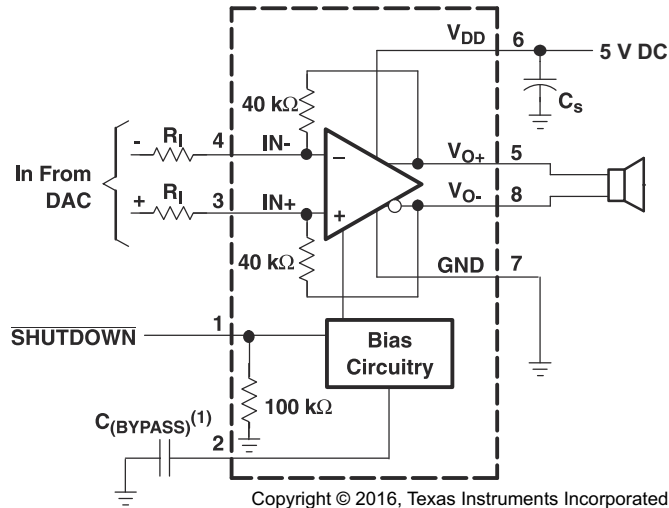
### 7.1 Application Information

The TPA6211A1-Q1 is a fully-differential amplifier designed to drive a speaker with at least 3-Ω impedance while consuming only 20-mm<sup>2</sup> total printed-circuit board (PCB) area in most applications.

### 7.2 Typical Applications

図 7-1 shows a typical application circuit for the TPA6211A1-Q1 with a speaker, input resistors, and supporting power supply decoupling capacitors.

#### 7.2.1 Typical Differential Input Application



A.  $C_{\text{BYPASS}}$  is optional

図 7-1. Typical Differential Input Application Schematic

Typical values are shown in 表 7-1.

表 7-1. Typical Component Values

| COMPONENT                 | VALUE   |
|---------------------------|---------|
| $R_I$                     | 40 kΩ   |
| $C_{\text{BYPASS}}^{(1)}$ | 0.22 μF |
| $C_S$                     | 1 μF    |
| $C_I$                     | 0.22 μF |

(1)  $C_{\text{BYPASS}}$  is optional.

#### 7.2.1.1 Design Requirements

For this design example, use the parameters listed in 表 7-2 as the input parameters.

表 7-2. Design Parameters

| PARAMETER            | EXAMPLE VALUE    |
|----------------------|------------------|
| Power supply voltage | 2.5 V to 5.5 V   |
| Current              | 4 mA to 5 mA     |
| Shutdown             | High > 1.55 V    |
|                      | Low < 0.5 V      |
| Speaker              | 3 Ω, 4 Ω, or 8 Ω |

### 7.2.1.2 Detailed Design Procedure

#### 7.2.1.2.1 Resistors ( $R_I$ )

The input resistor ( $R_I$ ) can be selected to set the gain of the amplifier according to 式 19.

$$\text{Gain} = \frac{R_F}{R_I} \quad (19)$$

The internal feedback resistors ( $R_F$ ) are trimmed to 40 kΩ.

Resistor matching is very important in fully differential amplifiers. The balance of the output on the reference voltage depends on matched ratios of the resistors. CMRR, PSRR, and the cancellation of the second harmonic distortion diminishes if resistor mismatch occurs. Therefore, TI recommends 1%-tolerance resistors or better to optimize performance.

#### 7.2.1.2.2 Bypass Capacitor ( $C_{\text{BYPASS}}$ ) and Start-Up Time

The internal voltage divider at the BYPASS pin of this device sets a mid-supply voltage for internal references and sets the output common mode voltage to  $V_{\text{DD}} / 2$ . Adding a capacitor filters any noise into this pin, increasing  $k_{\text{SVR}}$ .  $C_{\text{BYPASS}}$  also determines the rise time of  $V_{\text{O+}}$  and  $V_{\text{O-}}$  when the device exits shutdown. The larger the capacitor, the slower the rise time.

#### 7.2.1.2.3 Input Capacitor ( $C_I$ )

The TPA6211A1-Q1 device does not require input coupling capacitors when driven by a differential input source biased from 0.5 V to  $V_{\text{DD}} - 0.8$  V. Use 1% tolerance or better gain-setting resistors if not using input coupling capacitors.

In the single-ended input application, an input capacitor ( $C_I$ ) is required to allow the amplifier to bias the input signal to the proper DC level. In this case,  $C_I$  and  $R_I$  form a high-pass filter with the corner frequency defined in 式 20.

$$f_c = \frac{1}{2\pi R_I C_I} \quad (20)$$

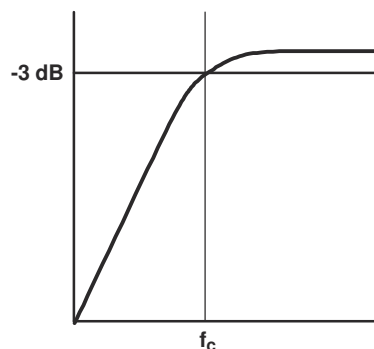


図 7-2. Input Filter Cutoff Frequency

The value of  $C_I$  is an important consideration, as it directly affects the bass (low frequency) performance of the circuit. Consider the example where  $R_I$  is 10 k $\Omega$  and the specification calls for a flat bass response down to 100 Hz. 式 20 is reconfigured as 式 21.

$$C_I = \frac{1}{2\pi R_I f_c} \quad (21)$$

In this example,  $C_I$  is 0.16  $\mu$ F, so the likely choice ranges from 0.22  $\mu$ F to 0.47  $\mu$ F. TI recommends the use of ceramic capacitors because they are the best choice in preventing leakage current. When polarized capacitors are used, the positive side of the capacitor faces the amplifier input in most applications. The input DC level is held at  $V_{DD} / 2$ , typically higher than the source DC level. Confirming the capacitor polarity in the application is important.

#### 7.2.1.2.4 Band-Pass Filter ( $R_I$ , $C_I$ , and $C_F$ )

Having signal filtering beyond the one-pole high-pass filter formed by the combination of  $C_I$  and  $R_I$  can be desirable. A low-pass filter can be added by placing a capacitor ( $C_F$ ) between the inputs and outputs, forming a band-pass filter.

An example of when this technique might be used would be in an application where the desirable pass-band range is between 100 Hz and 10 kHz, with a gain of 4 V/V. 式 22 to 式 29 allow the proper values of  $C_F$  and  $C_I$  to be determined.

##### 7.2.1.2.4.1 Step 1: Low-Pass Filter

$$f_{c(LPF)} = \frac{1}{2\pi R_F C_F} \quad (22)$$

$$f_{c(LPF)} = \frac{1}{2\pi 40\text{k}\Omega C_F} \quad (23)$$

Therefore,

$$C_F = \frac{1}{2\pi 40\text{k}\Omega f_{c(LPF)}} \quad (24)$$

Substituting 10 kHz for  $f_{c(LPF)}$  and solving for  $C_F$ :

$$C_F = 398\text{ pF} \quad (25)$$

##### 7.2.1.2.4.2 Step 2: High-Pass Filter

$$f_{c(HPF)} = \frac{1}{2\pi R_I C_I} \quad (26)$$

Because the application in this case requires a gain of 4 V/V,  $R_I$  must be set to 10 k $\Omega$ .

Substituting  $R_I$  into 式 26.

$$f_{c(HPF)} = \frac{1}{2\pi 10\text{k}\Omega C_I} \quad (27)$$

Therefore,

$$C_I = \frac{1}{2\pi 10 \text{ k}\Omega f_{c(\text{HPF})}} \quad (28)$$

Substituting 100 Hz for  $f_{c(\text{HPF})}$  and solving for  $C_I$ :

$$C_I = 0.16 \text{ }\mu\text{F} \quad (29)$$

At this point, a first-order band-pass filter has been created with the low-frequency cutoff set to 100 Hz and the high-frequency cutoff set to 10 kHz.

The process can be taken a step further by creating a second-order high-pass filter. This is accomplished by placing a resistor ( $R_a$ ) and capacitor ( $C_a$ ) in the input path.  $R_a$  must be at least 10 times smaller than  $R_I$ ; otherwise its value has a noticeable effect on the gain, as  $R_a$  and  $R_I$  are in series.

#### 7.2.1.2.4.3 Step 3: Additional Low-Pass Filter

$R_a$  must be at least ten-times smaller than  $R_I$ . Set  $R_a = 1 \text{ k}\Omega$

$$f_{c(\text{LPF})} = \frac{1}{2\pi R_a C_a} \quad (30)$$

Therefore,

$$C_a = \frac{1}{2\pi 1 \text{ k}\Omega f_{c(\text{LPF})}} \quad (31)$$

Substituting 10 kHz for  $f_{c(\text{LPF})}$  and solving for  $C_a$ :

$$C_a = 160 \text{ pF} \quad (32)$$

Figure 7-3 is a bode plot for the band-pass filter in the previous example. Figure 7-8 shows how to configure the TPA6211A1-Q1 device as a band-pass filter.

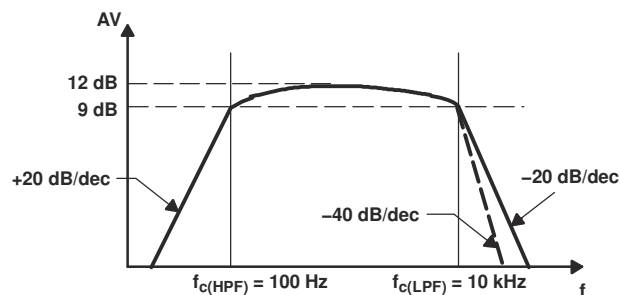


Figure 7-3. Bode Plot

#### 7.2.1.2.5 Decoupling Capacitor ( $C_S$ )

The TPA6211A1-Q1 device is a high-performance CMOS audio amplifier that requires adequate power supply decoupling to ensure the output total harmonic distortion (THD) is as low as possible. Power-supply decoupling also prevents oscillations for long lead lengths between the amplifier and the speaker. For higher frequency transients, spikes, or digital hash on the line, a good low equivalent-series-resistance (ESR) ceramic capacitor, typically 0.1  $\mu\text{F}$  to 1  $\mu\text{F}$ , placed as close as possible to the device  $V_{DD}$  lead works best. For filtering lower frequency noise signals, a 10- $\mu\text{F}$  or greater capacitor placed near the audio power amplifier also helps, but is not required in most applications because of the high PSRR of this device.

### 7.2.1.2.6 Using Low-ESR Capacitors

Low-ESR capacitors are recommended throughout this applications section. A real (as opposed to ideal) capacitor can be modeled simply as a resistor in series with an ideal capacitor. The voltage drop across this resistor minimizes the beneficial effects of the capacitor in the circuit. The lower the equivalent value of this resistance the more the real capacitor behaves like an ideal capacitor.

### 7.2.1.3 Application Curves

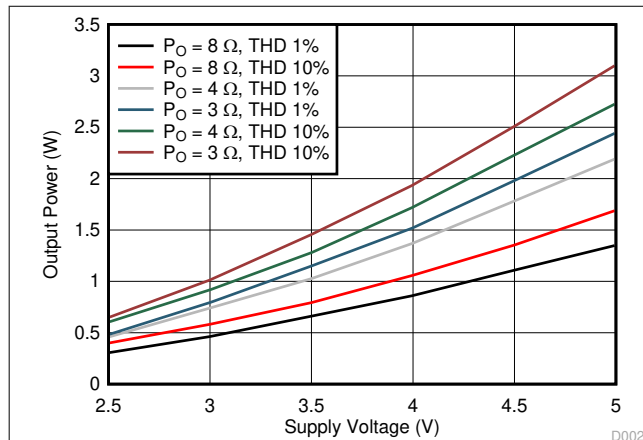


Figure 7-4. Output Power vs Supply Voltage

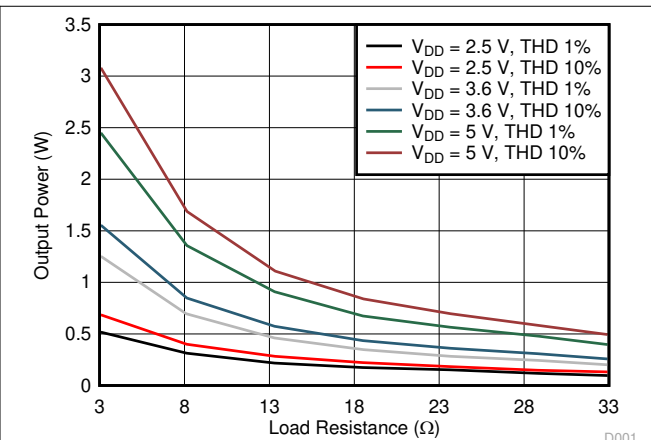
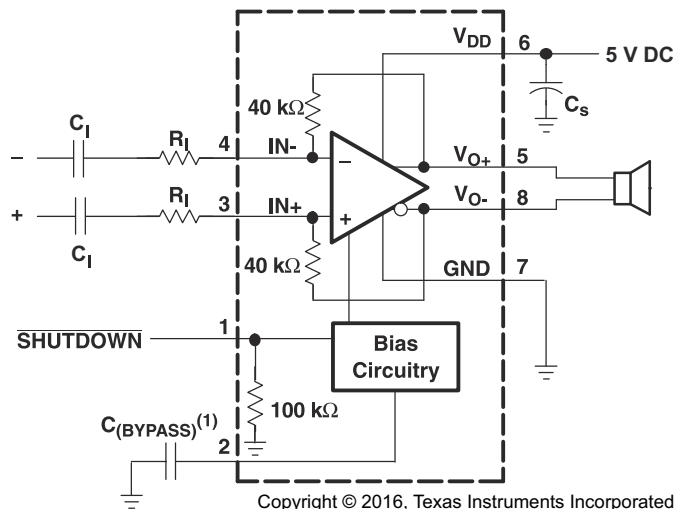


Figure 7-5. Output Power vs Load Resistance

### 7.2.2 Other Application Circuits

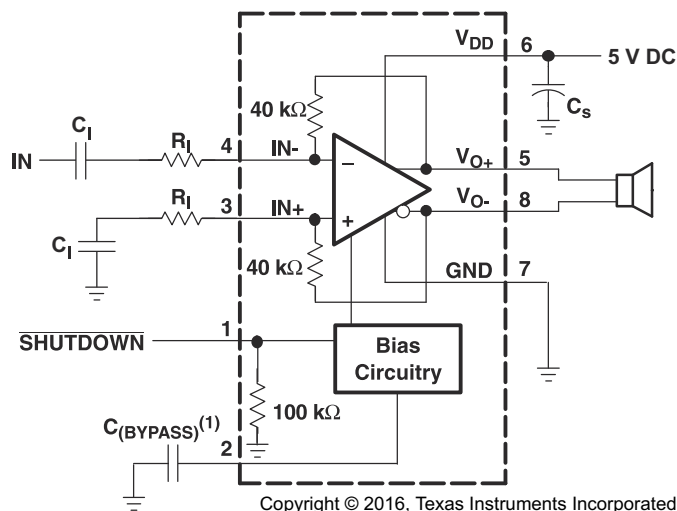
Figure 7-6, Figure 7-7, and Figure 7-8 show example circuits using the TPA6211A1-Q1 device.



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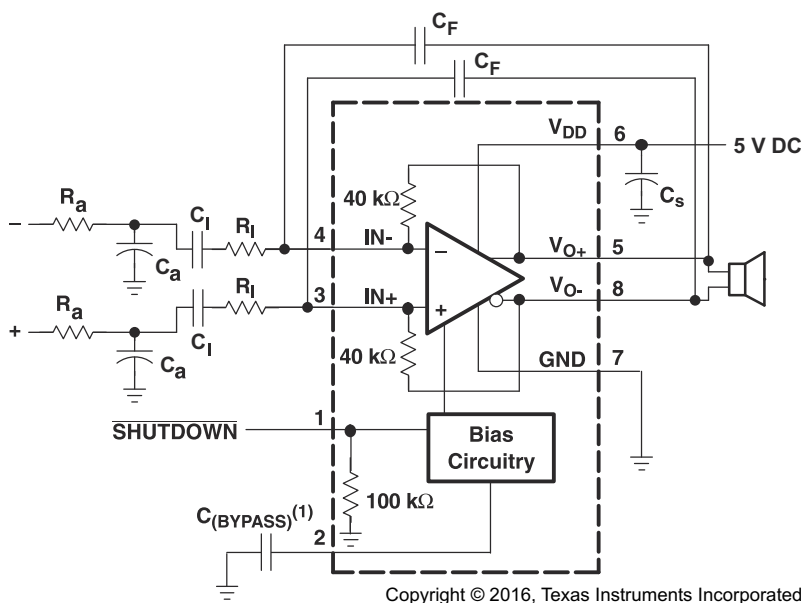
A.  $C_{\text{BYPASS}}$  is optional

Figure 7-6. Differential Input Application Schematic Optimized With Input Capacitors



A.  $C_{(BYPASS)}$  is optional

図 7-7. Single-Ended Input Application Schematic



A.  $C_{(BYPASS)}$  is optional

図 7-8. Differential Input Application Schematic With Input Bandpass Filter

### 7.3 Power Supply Recommendations

The TPA6211A1-Q1 device is designed to operate from an input voltage supply range between 2.5 V and 5.5 V. Therefore, the output voltage range of power supply must be within this range and well regulated. The current capability of upper power should not exceed the maximum current limit of the power switch.

#### 7.3.1 Power Supply Decoupling Capacitor

The TPA6211A1-Q1 device requires adequate power supply decoupling to ensure a high efficiency operation with low total harmonic distortion (THD). Place a low equivalent series resistance (ESR) ceramic capacitor, typically 0.1  $\mu$ F, as close as possible of the  $V_{DD}$  pin. This choice of capacitor and placement helps with higher frequency transients, spikes, or digital hash on the line. TI recommends placing a 2.2- $\mu$ F to 10- $\mu$ F capacitor on

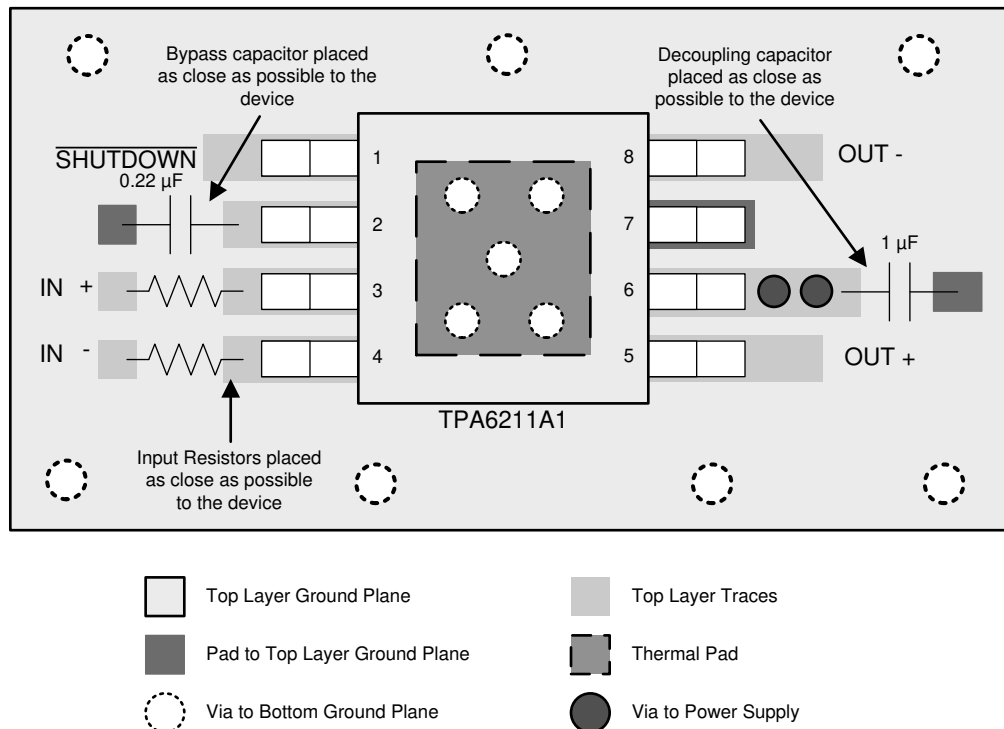
the  $V_{DD}$  supply trace. This larger capacitor acts as a charge reservoir, providing energy faster than the board supply, thus helping to prevent any droop in the supply voltage.

## 7.4 Layout

### 7.4.1 Layout Guidelines

Place all the external components close to the TPA6211A1-Q1 device. The input resistors need to be close to the device input pins so noise does not couple on the high impedance nodes between the input resistors and the input amplifier of the device. Placing the decoupling capacitors,  $C_S$  and  $C_{BYPASS}$ , close to the TPA6211A1-Q1 device is important for the efficiency of the amplifier. Any resistance or inductance in the trace between the device and the capacitor can cause a loss in efficiency.

### 7.4.2 Layout Example



**7-9. TPA6211A1-Q1 8-Pin HVSSOP (DGN) Board Layout**

## 8 Device and Documentation Support

### 8.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 8.2 サポート・リソース

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[テキサス・インスツルメンツ用語集](#) この用語集には、用語や略語の一覧および定義が記載されています。

## 9 Revision History

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

| Changes from Revision F (February 2024) to Revision G (May 2024) | Page |
|------------------------------------------------------------------|------|
| • Changed the <i>ESD Ratings</i> for CDM to $\pm 1000V$ .....    | 4    |

| Changes from Revision E (August 2019) to Revision F (February 2024) | Page |
|---------------------------------------------------------------------|------|
| • 「特長」の「デバイス HBM ESD 分類レベル」を変更: 車載アプリケーション認定済み.....                 | 1    |
| • Changed the <i>ESD Ratings</i> for HBM to $\pm 2000V$ .....       | 4    |

| Changes from Revision D (August 2019) to Revision E (August 2019) | Page |
|-------------------------------------------------------------------|------|
| • パッケージを HVSSOP に変更.....                                          | 1    |
| • Changed packaging to HVSSOP.....                                | 4    |
| • Changed packaging to HVSSOP.....                                | 25   |

| Changes from Revision C (August 2016) to Revision D (August 2019) | Page |
|-------------------------------------------------------------------|------|
| • 「特長」から AEC-Q100 を削除車載アプリケーション認定済み.....                          | 1    |
| • 「特長」を削除: 温度グレード 2.....                                          | 1    |

- Changed the *ESD Ratings* table.....4

**Changes from Revision B (January 2014) to Revision C (August 2016) Page**

- 「製品情報」表、「ESD 定格」表、「機能説明」セクション、「デバイスの機能モード」セクション、「アプリケーションと実装」セクション、「電源に関する推奨事項」セクション、「レイアウト」セクション、「デバイスおよびドキュメントのサポート」セクション、「メカニカル、パッケージ、および注文情報」セクションを追加。 ..... 1
- Added missing Max Ambient Temperature values to 表 6-1 ..... 13
- Changed 45.9 to 71.7, 1.27 to 1.25, and 91.7 to 60 in 式 13 ..... 13

**Changes from Revision A (November 2013) to Revision B (January 2014) Page**

- Added three new equations to the *DIFFERENTIAL OUTPUT VERSUS SINGLE-ENDED OUTPUT* section in order to show difference between single-ended and differential output..... 17

**Changes from Revision \* (June 2011) to Revision A (November 2013) Page**

- 「特長」リストから「携帯電話および PDA 用に設計」を削除 ..... 1
- Deleted *Ordering Information* table..... 3
- Changed reference from "equation 6" to 式 26 in the *High-Pass Filter* section.....21

## 10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

## PACKAGING INFORMATION

| Orderable part number | Status<br>(1) | Material type<br>(2) | Package   Pins   | Package qty   Carrier | RoHS<br>(3) | Lead finish/<br>Ball material<br>(4) | MSL rating/<br>Peak reflow<br>(5) | Op temp (°C) | Part marking<br>(6) |
|-----------------------|---------------|----------------------|------------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| TPA6211A1TDGNRQ1      | Active        | Production           | HVSSOP (DGN)   8 | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-3-260C-168 HR               | -40 to 105   | 6211Q               |
| TPA6211A1TDGNRQ1.B    | Active        | Production           | HVSSOP (DGN)   8 | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-3-260C-168 HR               | -40 to 105   | 6211Q               |

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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### OTHER QUALIFIED VERSIONS OF TPA6211A1-Q1 :

- Catalog : [TPA6211A1](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product

## TAPE AND REEL INFORMATION



\*All dimensions are nominal

| Device           | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|------------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| TPA6211A1TDGNRQ1 | HVSSOP       | DGN             | 8    | 2500 | 330.0              | 12.4               | 5.3     | 3.4     | 1.4     | 8.0     | 12.0   | Q1            |
| TPA6211A1TDGNRQ1 | HVSSOP       | DGN             | 8    | 2500 | 330.0              | 12.4               | 5.3     | 3.4     | 1.4     | 8.0     | 12.0   | Q1            |

## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

| Device           | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|------------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TPA6211A1TDGNRQ1 | HVSSOP       | DGN             | 8    | 2500 | 353.0       | 353.0      | 32.0        |
| TPA6211A1TDGNRQ1 | HVSSOP       | DGN             | 8    | 2500 | 346.0       | 346.0      | 29.0        |

## GENERIC PACKAGE VIEW

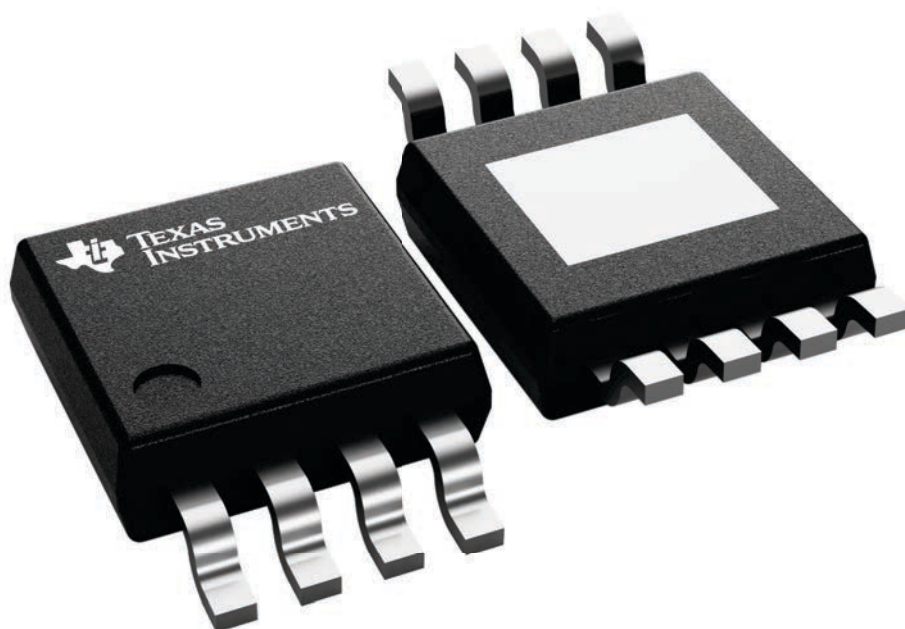
**DGN 8**

**PowerPAD™ HVSSOP - 1.1 mm max height**

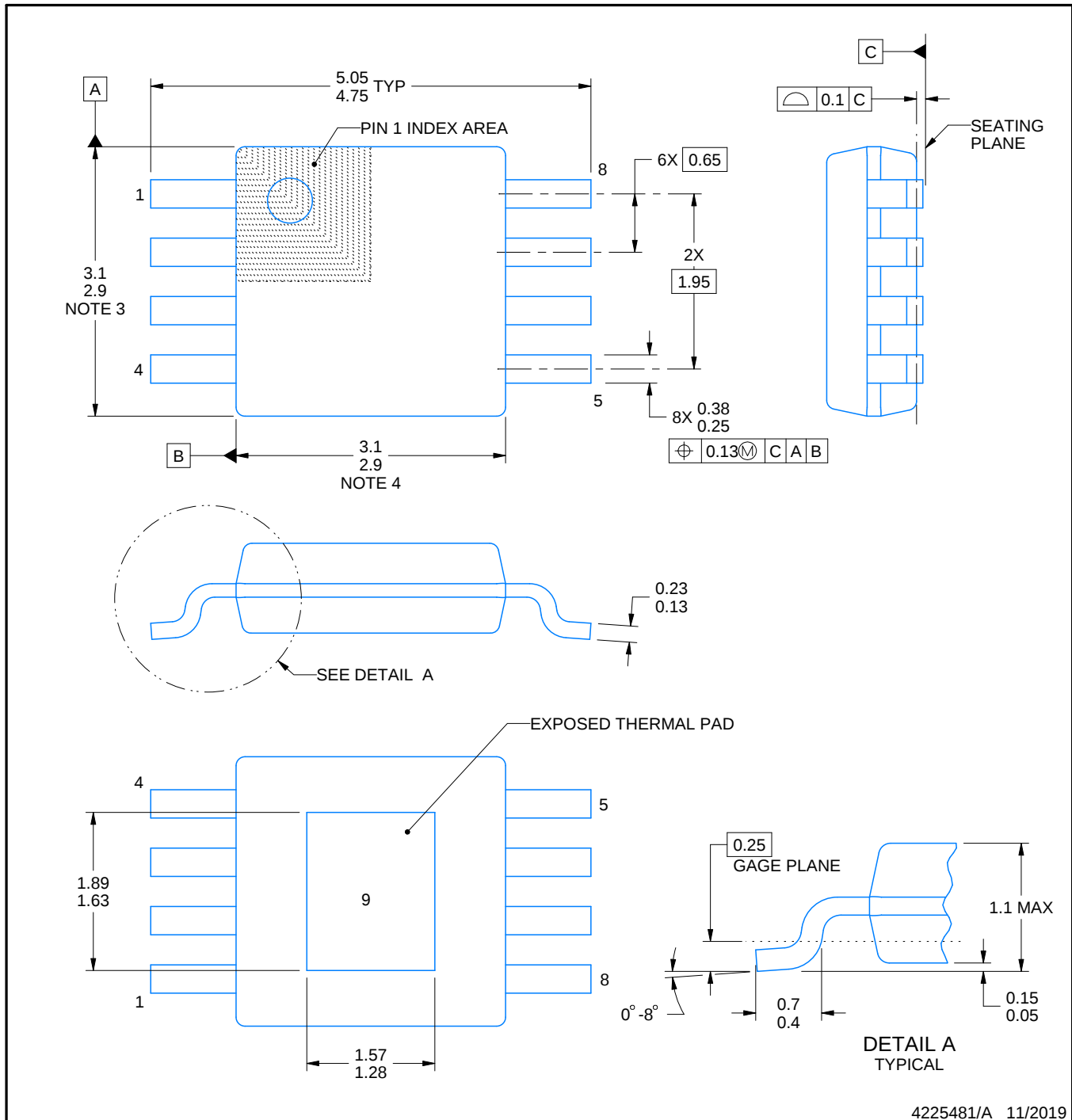
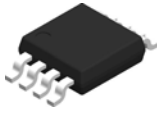
3 x 3, 0.65 mm pitch

SMALL OUTLINE PACKAGE

This image is a representation of the package family, actual package may vary.  
Refer to the product data sheet for package details.



4225482/B



4225481/A 11/2019

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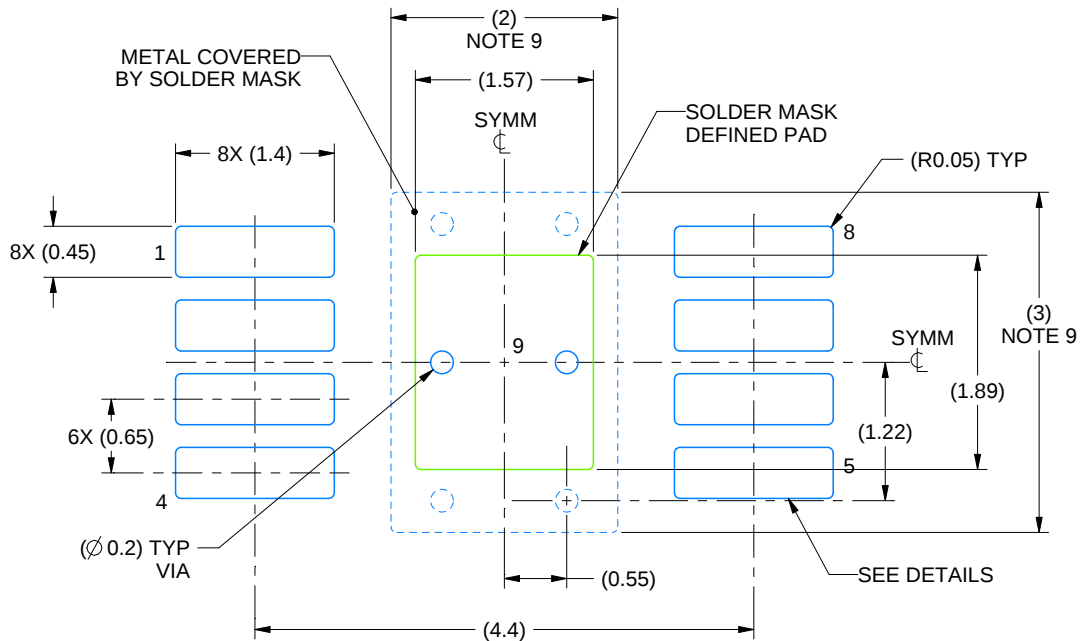
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.

# EXAMPLE BOARD LAYOUT

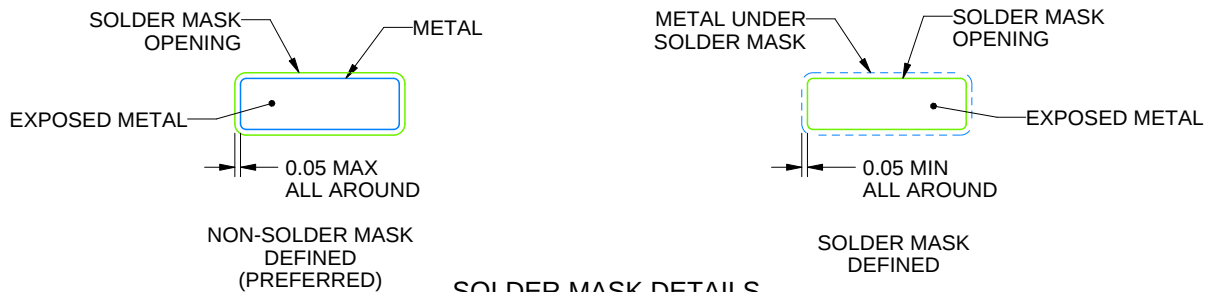
DGN0008D

PowerPAD™ VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE: 15X



SOLDER MASK DETAILS

4225481/A 11/2019

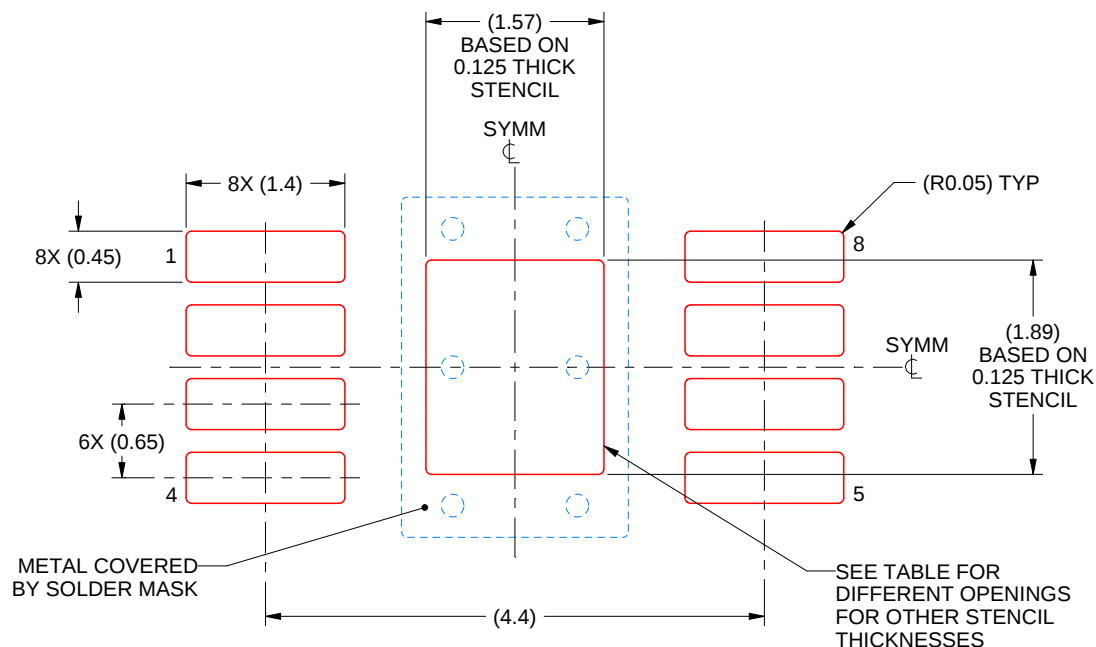
NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.

**DGN0008D**

# PowerPAD™ VSSOP - 1.1 mm max height

## SMALL OUTLINE PACKAGE



## SOLDER PASTE EXAMPLE

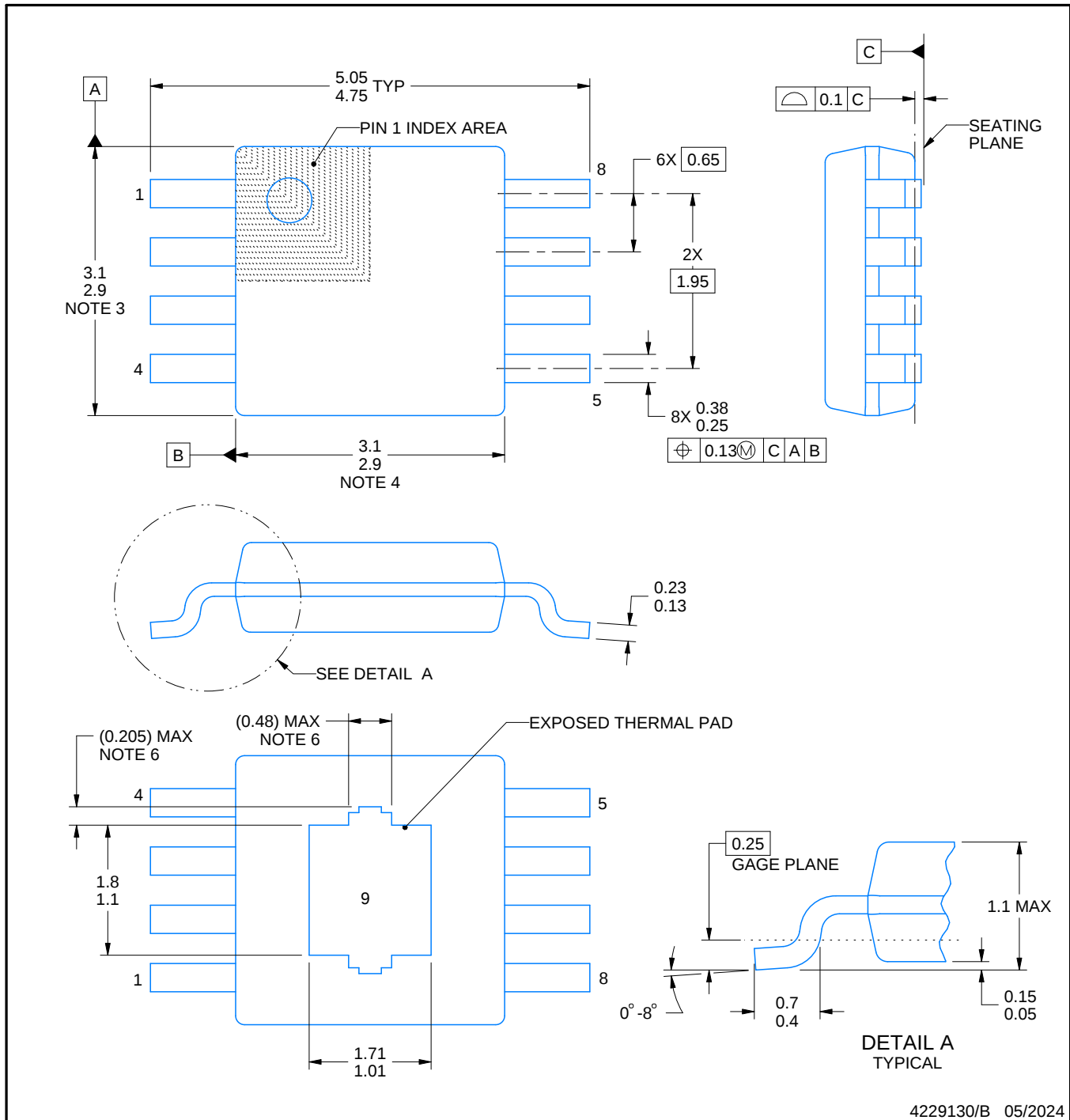
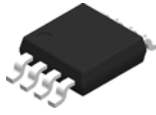
EXPOSED PAD 9:  
100% PRINTED SOLDER COVERAGE BY AREA  
SCALE: 15X

| STENCIL THICKNESS | SOLDER STENCIL OPENING |
|-------------------|------------------------|
| 0.1               | 1.76 X 2.11            |
| 0.125             | 1.57 X 1.89 (SHOWN)    |
| 0.15              | 1.43 X 1.73            |
| 0.175             | 1.33 X 1.60            |

4225481/A 11/2019

NOTES: (continued)

10. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
11. Board assembly site may have different recommendations for stencil design.



4229130/B 05/2024

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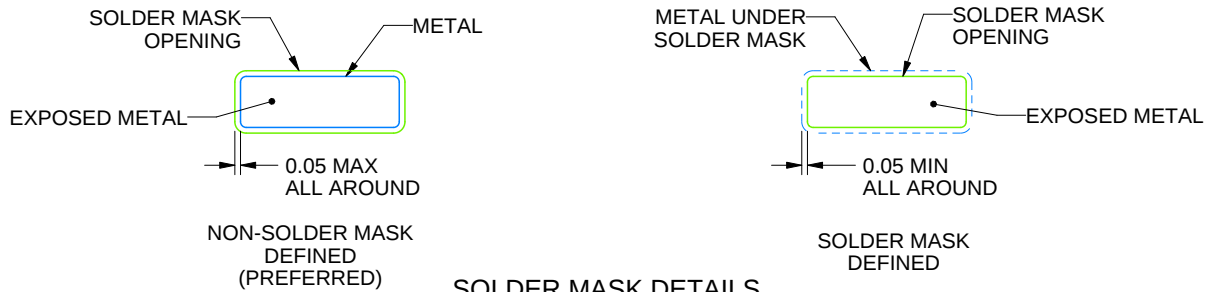
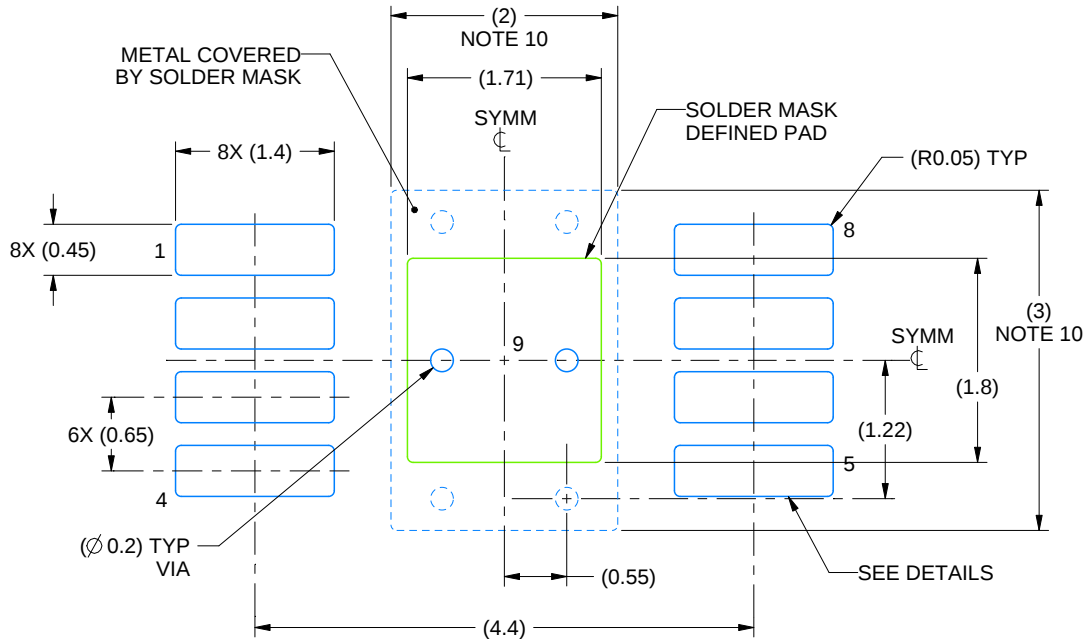
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
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4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.
6. Features may differ or may not be present.

# EXAMPLE BOARD LAYOUT

DGN0008H

PowerPAD™ VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



4229130/B 05/2024

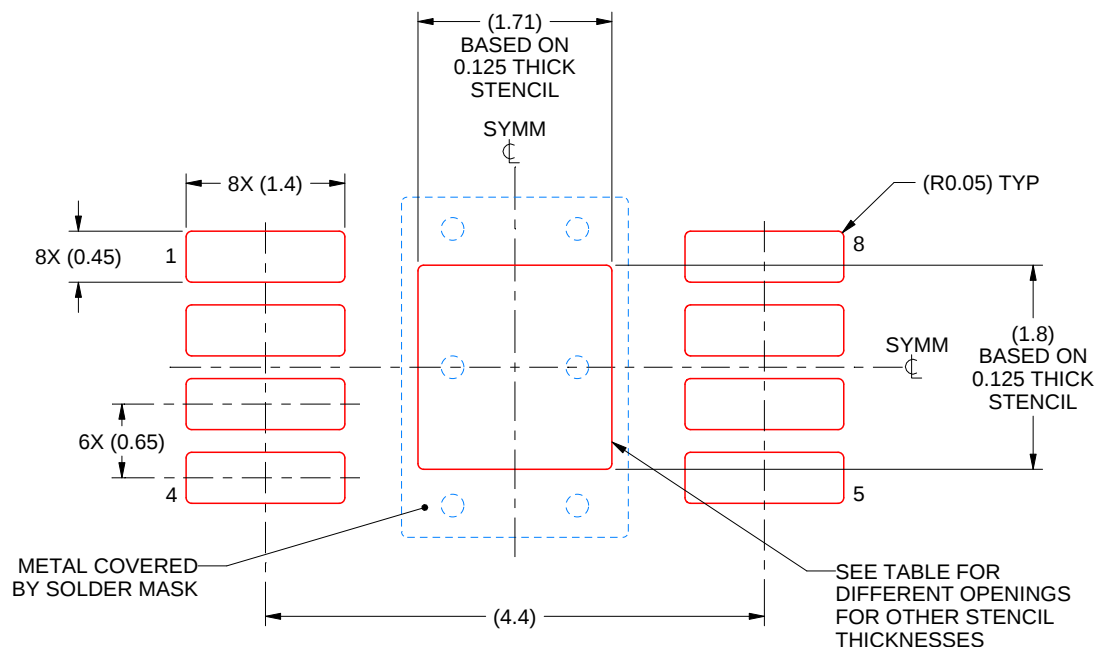
NOTES: (continued)

7. Publication IPC-7351 may have alternate designs.
8. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
9. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
10. Size of metal pad may vary due to creepage requirement.

**DGN0008H**

# PowerPAD™ VSSOP - 1.1 mm max height

## SMALL OUTLINE PACKAGE



## SOLDER PASTE EXAMPLE

EXPOSED PAD 9:  
100% PRINTED SOLDER COVERAGE BY AREA  
SCALE: 15X

| STENCIL THICKNESS | SOLDER STENCIL OPENING |
|-------------------|------------------------|
| 0.1               | 1.91 X 2.01            |
| 0.125             | 1.71 X 1.80 (SHOWN)    |
| 0.15              | 1.56 X 1.64            |
| 0.175             | 1.45 X 1.52            |

4229130/B 05/2024

NOTES: (continued)

11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.

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